

devices are designed to drive 12 V automotive grounded loads through a 3 V and 5 V CMOS-compatible interface, and to provide protection and diagnostics.

The devices integrate advanced protective functions such as load current limitation, overload active management by power limitation and overtemperature shutdown with configurable latch-off.

A  $\overline{\text{FaultRST}}$  pin unlatches the output in case of fault or disables the latch-off functionality.

A dedicated multifunction multiplexed analog output pin delivers sophisticated diagnostic functions including high precision proportional load current sense, supply voltage feedback and chip temperature sense, in addition to the detection of overload and short circuit to ground, short to  $V_{CC}$  and OFF-state open-load.

A sense enable pin allows OFF-state diagnosis to be disabled during the module low-power mode as well as external sense resistor sharing among similar devices.

## 1 Block diagram and pin description

Figure 1. Block diagram

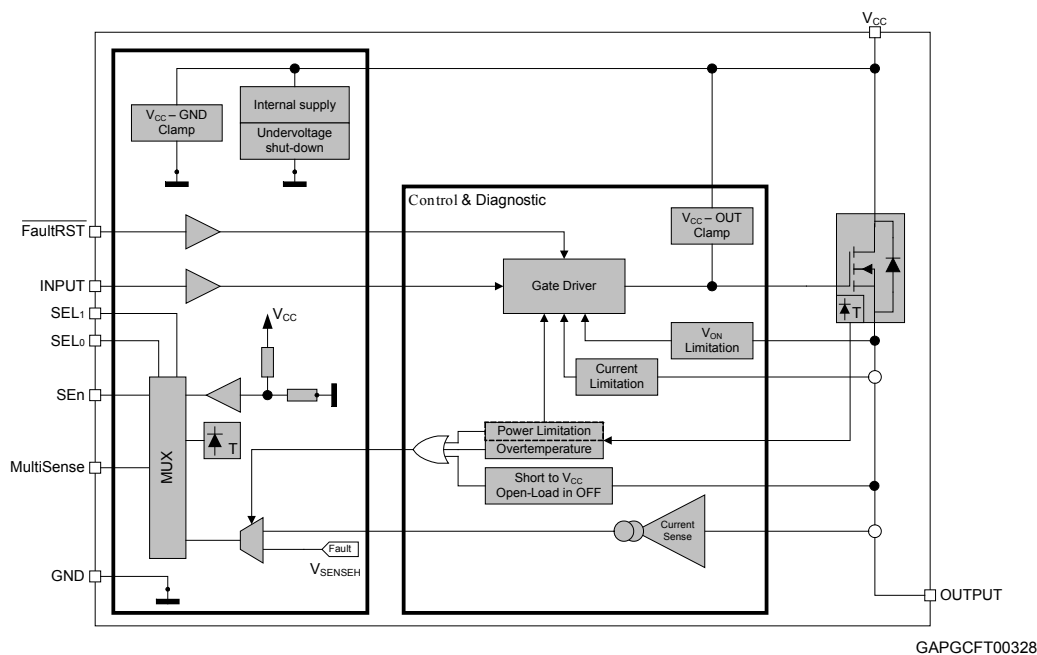
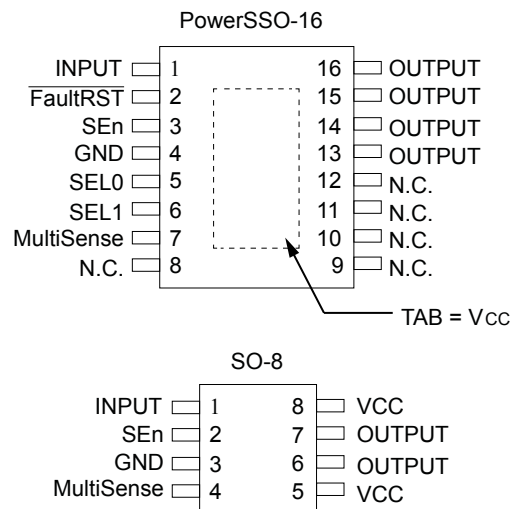


Table 1. Pin functions

| Name                         | Function                                                                                                                                               |
|------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------|
| V <sub>CC</sub>              | Battery connection.                                                                                                                                    |
| OUTPUT                       | Power outputs.                                                                                                                                         |
| GND                          | Ground connection. Must be reverse battery protected by an external diode / resistor network.                                                          |
| INPUT                        | Voltage controlled input pin with hysteresis, compatible with 3 V and 5 V CMOS outputs. It controls output switch state.                               |
| MultiSense                   | Multiplexed analog sense output pin; it delivers a current proportional to the selected diagnostic: load current, supply voltage or chip temperature.  |
| SEn                          | Active high compatible with 3 V and 5 V CMOS outputs pin; it enables the MultiSense diagnostic pin.                                                    |
| SEL <sub>0,1</sub>           | Active high compatible with 3 V and 5 V CMOS outputs pin; they address the MultiSense multiplexer.                                                     |
| $\overline{\text{FaultRST}}$ | Active low compatible with 3 V and 5 V CMOS outputs pin; it unlatches the output in case of fault; If kept low, sets the outputs in auto-restart mode. |

**Figure 2. Configuration diagram (top view)**



GAPG2601151129CFT

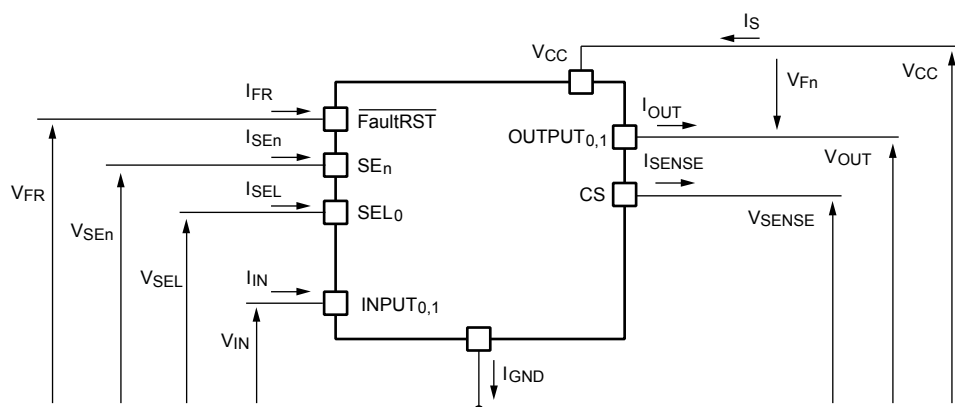
**Table 2. Suggested connections for unused and not connected pins**

| Connection / pin | MultiSense            | N.C.             | Output      | Input                  | SEn, SELx, FaultRST    |
|------------------|-----------------------|------------------|-------------|------------------------|------------------------|
| Floating         | Not allowed           | X <sup>(1)</sup> | X           | X                      | X                      |
| To ground        | Through 1 kΩ resistor | X                | Not allowed | Through 15 kΩ resistor | Through 15 kΩ resistor |

1. X: do not care.

## 2 Electrical specification

**Figure 3. Current and voltage conventions**



GADG2203170950PS

**Note:**  $V_F = V_{OUT} - V_{CC}$  during reverse battery condition.

### 2.1 Absolute maximum ratings

Stressing the device above the rating listed in [Table 3. Absolute maximum ratings](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to the conditions in table below for extended periods may affect device reliability.

**Table 3. Absolute maximum ratings**

| Symbol      | Parameter                                                                                     | Value              | Unit |
|-------------|-----------------------------------------------------------------------------------------------|--------------------|------|
| $V_{CC}$    | DC supply voltage                                                                             | 38                 | V    |
| $-V_{CC}$   | Reverse DC supply voltage                                                                     | 0.3                |      |
| $V_{CCPK}$  | Maximum transient supply voltage (ISO 16750-2:2010 Test B clamped to 40 V; $R_L = 4 \Omega$ ) | 40                 | V    |
| $V_{CCJS}$  | Maximum jump start voltage for single pulse short-circuit protection                          | 28                 | V    |
| $-I_{GND}$  | DC reverse ground pin current                                                                 | 200                | mA   |
| $I_{OUT}$   | OUTPUT DC output current                                                                      | Internally limited | A    |
| $-I_{OUT}$  | Reverse DC output current                                                                     | 11                 |      |
| $I_{IN}$    | INPUT DC input current                                                                        | -1 to 10           | mA   |
| $I_{SEn}$   | SEn DC input current                                                                          |                    |      |
| $I_{SEL}$   | SEL <sub>0,1</sub> DC input current                                                           |                    |      |
| $I_{FR}$    | FaultRST DC input current                                                                     |                    |      |
| $V_{FR}$    | FaultRST DC input voltage                                                                     | 7.5                | V    |
| $I_{SENSE}$ | MultiSense pin DC output current ( $V_{GND} = V_{CC}$ and $V_{SENSE} < 0$ V)                  | 10                 | mA   |
|             | MultiSense pin DC output current in reverse ( $V_{CC} < 0$ V)                                 | -20                |      |
| $E_{MAX}$   | Maximum switching energy (single pulse) ( $T_{DEMAG} = 0.4$ ms; $T_{jstart} = 150$ °C)        | 36                 | mJ   |

| Symbol    | Parameter                                | Value      | Unit |
|-----------|------------------------------------------|------------|------|
| $V_{ESD}$ | Electrostatic discharge (JEDEC 22A-114F) | 4000       | V    |
|           | • INPUT                                  | 2000       | V    |
|           | • MultiSense                             | 4000       | V    |
|           | • SEn, SEL <sub>0,1</sub> , FaultRST     | 4000       | V    |
|           | • OUTPUT                                 | 4000       | V    |
|           | • V <sub>CC</sub>                        | 4000       | V    |
| $V_{ESD}$ | Charge device model (CDM-AEC-Q100-011)   | 750        | V    |
| $T_j$     | Junction operating temperature           | -40 to 150 | °C   |
| $T_{stg}$ | Storage temperature                      | -55 to 150 |      |

## 2.2 Thermal data

**Table 4. Thermal data**

| Symbol          | Parameter                                                            | Typ. value |             | Unit |
|-----------------|----------------------------------------------------------------------|------------|-------------|------|
|                 |                                                                      | SO-8       | PowerSSO-16 |      |
| $R_{thj-board}$ | Thermal resistance junction-board (JEDEC JESD 51-8) <sup>(1)</sup>   | 29         | 6.2         | °C/W |
| $R_{thj-amb}$   | Thermal resistance junction-ambient (JEDEC JESD 51-2) <sup>(2)</sup> | 67         | 57          |      |
| $R_{thj-amb}$   | Thermal resistance junction-ambient (JEDEC JESD 51-2)                | 45         | 23.5        |      |

1. Device mounted on four-layers 2s2p PCB

2. Device mounted on two-layers 2s0p PCB with 2 cm<sup>2</sup> heatsink copper trace

## 2.3 Main electrical characteristics

7 V < V<sub>CC</sub> < 28 V; -40°C < T<sub>j</sub> < 150°C, unless otherwise specified.

All typical values refer to V<sub>CC</sub> = 13 V; T<sub>j</sub> = 25°C, unless otherwise specified.

**Table 5. Power section**

| Symbol                | Parameter                        | Test conditions                                                        | Min. | Typ. | Max. | Unit |
|-----------------------|----------------------------------|------------------------------------------------------------------------|------|------|------|------|
| V <sub>CC</sub>       | Operating supply voltage         |                                                                        | 4    | 13   | 28   | V    |
| V <sub>USD</sub>      | Undervoltage shutdown            |                                                                        |      |      | 4    | V    |
| V <sub>USDReset</sub> | Undervoltage shutdown reset      |                                                                        |      |      | 5    | V    |
| V <sub>USDhyst</sub>  | Undervoltage shutdown hysteresis |                                                                        |      | 0.3  |      | V    |
| R <sub>ON</sub>       | On-state resistance              | I <sub>OUT</sub> = 2.5 A; T <sub>j</sub> = 25°C                        |      | 40   |      | mΩ   |
|                       |                                  | I <sub>OUT</sub> = 2.5 A; T <sub>j</sub> = 150°C                       |      |      | 80   |      |
|                       |                                  | I <sub>OUT</sub> = 2.5 A; V <sub>CC</sub> = 4 V; T <sub>j</sub> = 25°C |      |      | 60   |      |
| V <sub>clamp</sub>    | Clamp voltage                    | I <sub>S</sub> = 20 mA; 25°C < T <sub>j</sub> < 150°C                  | 41   | 46   | 52   | V    |
|                       |                                  | I <sub>S</sub> = 20 mA; T <sub>j</sub> = -40°C                         | 38   |      |      | V    |

| Symbol               | Parameter                                                                  | Test conditions                                                                                                                                                                                            | Min. | Typ. | Max. | Unit          |
|----------------------|----------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $I_{\text{STBY}}$    | Supply current in standby at $V_{\text{CC}} = 13 \text{ V}$ <sup>(1)</sup> | $V_{\text{CC}} = 13 \text{ V};$<br>$V_{\text{IN}} = V_{\text{OUT}} = V_{\text{FR}} = V_{\text{SEn}} = 0 \text{ V};$<br>$V_{\text{SEL0,1}} = 0 \text{ V}; T_{\text{J}} = 25^{\circ}\text{C}$                |      |      | 0.5  | $\mu\text{A}$ |
|                      |                                                                            | $V_{\text{CC}} = 13 \text{ V};$<br>$V_{\text{IN}} = V_{\text{OUT}} = V_{\text{FR}} = V_{\text{SEn}} = 0 \text{ V};$<br>$V_{\text{SEL0,1}} = 0 \text{ V}; T_{\text{J}} = 85^{\circ}\text{C}$ <sup>(2)</sup> |      |      | 0.5  |               |
|                      |                                                                            | $V_{\text{CC}} = 13 \text{ V};$<br>$V_{\text{IN}} = V_{\text{OUT}} = V_{\text{FR}} = V_{\text{SEn}} = 0 \text{ V};$<br>$V_{\text{SEL0,1}} = 0 \text{ V}; T_{\text{J}} = 125^{\circ}\text{C}$               |      |      | 3    |               |
| $t_{\text{D\_STBY}}$ | Standby mode blanking time                                                 | $V_{\text{CC}} = 13 \text{ V};$<br>$V_{\text{IN}} = V_{\text{OUT}} = V_{\text{FR}} = V_{\text{SEL0,1}} = 0 \text{ V};$<br>$V_{\text{SEn}} = 5 \text{ V to } 5 \text{ V}$                                   | 60   | 300  | 550  | $\mu\text{s}$ |
| $I_{\text{S(ON)}}$   | Supply current                                                             | $V_{\text{CC}} = 13 \text{ V}; V_{\text{SEn}} = 0 \text{ V};$<br>$V_{\text{SEL0,1}} = V_{\text{FR}} = 0 \text{ V}; V_{\text{IN}} = 5 \text{ V}; I_{\text{OUT}} = 0 \text{ A}$                              |      | 3    | 5    | $\text{mA}$   |
| $I_{\text{GND(ON)}}$ | Control stage current consumption in ON-state. All channels active.        | $V_{\text{CC}} = 13 \text{ V}; V_{\text{SEn}} = 5 \text{ V};$<br>$V_{\text{FR}} = V_{\text{SEL0,1}} = 0 \text{ V}; V_{\text{IN}} = 5 \text{ V}; I_{\text{OUT}} = 2 \text{ A}$                              |      |      | 6    | $\text{mA}$   |
| $I_{\text{L(off)}}$  | Off-state output current at $V_{\text{CC}} = 13 \text{ V}$                 | $V_{\text{IN}} = V_{\text{OUT}} = 0 \text{ V}; V_{\text{CC}} = 13 \text{ V}; T_{\text{J}} = 25^{\circ}\text{C}$                                                                                            | 0    | 0.01 | 0.5  | $\mu\text{A}$ |
|                      |                                                                            | $V_{\text{IN}} = V_{\text{OUT}} = 0 \text{ V}; V_{\text{CC}} = 13 \text{ V}; T_{\text{J}} = 125^{\circ}\text{C}$                                                                                           | 0    |      | 3    |               |
| $V_{\text{F}}$       | Output - $V_{\text{CC}}$ diode voltage                                     | $I_{\text{OUT}} = -2.5 \text{ A}; T_{\text{J}} = 150^{\circ}\text{C}$                                                                                                                                      |      |      | 0.7  | $\text{V}$    |

1. PowerMOS leakage included.
2. Parameter specified by design; not subjected to production test.

**Table 6. Switching**

| $V_{\text{CC}} = 13 \text{ V}; -40^{\circ}\text{C} < T_{\text{J}} < 150^{\circ}\text{C}$ , unless otherwise specified |                                                               |                             |      |      |                    |                        |
|-----------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------|-----------------------------|------|------|--------------------|------------------------|
| Symbol                                                                                                                | Parameter                                                     | Test conditions             | Min. | Typ. | Max.               | Unit                   |
| $t_{\text{d(on)}}^{(1)}$                                                                                              | Turn-on delay time at $T_{\text{J}} = 25^{\circ}\text{C}$     | $R_{\text{L}} = 5.2 \Omega$ | 10   | 40   | 120                | $\mu\text{s}$          |
| $t_{\text{d(off)}}^{(1)}$                                                                                             | Turn-off delay time at $T_{\text{J}} = 25^{\circ}\text{C}$    |                             | 10   | 35   | 100                |                        |
| $(\text{d}V_{\text{OUT}}/\text{d}t)_{\text{on}}^{(1)}$                                                                | Turn-on voltage slope at $T_{\text{J}} = 25^{\circ}\text{C}$  | $R_{\text{L}} = 5.2 \Omega$ | 0.1  | 0.24 | 0.7                | $\text{V}/\mu\text{s}$ |
| $(\text{d}V_{\text{OUT}}/\text{d}t)_{\text{off}}^{(1)}$                                                               | Turn-off voltage slope at $T_{\text{J}} = 25^{\circ}\text{C}$ |                             | 0.1  | 0.28 | 0.7                |                        |
| $W_{\text{ON}}$                                                                                                       | Switching energy losses at turn-on ( $t_{\text{won}}$ )       | $R_{\text{L}} = 5.2 \Omega$ | —    | 0.32 | 0.4 <sup>(2)</sup> | $\text{mJ}$            |
| $W_{\text{OFF}}$                                                                                                      | Switching energy losses at turn-off ( $t_{\text{woff}}$ )     | $R_{\text{L}} = 5.2 \Omega$ | —    | 0.33 | 0.4 <sup>(2)</sup> | $\text{mJ}$            |
| $t_{\text{SKEW}}^{(1)}$                                                                                               | Differential Pulse skew ( $t_{\text{PHL}} - t_{\text{PLH}}$ ) | $R_{\text{L}} = 5.2 \Omega$ | -40  | 10   | 60                 | $\mu\text{s}$          |

1. See Figure 6. Switching time and Pulse skew.
2. Parameter guaranteed by design and characterization; not subjected to production test.

**Table 7. Logic inputs**

| $7 \text{ V} < V_{\text{CC}} < 28 \text{ V}; -40^{\circ}\text{C} < T_{\text{J}} < 150^{\circ}\text{C}$ |                         |                                 |      |      |      |               |
|--------------------------------------------------------------------------------------------------------|-------------------------|---------------------------------|------|------|------|---------------|
| Symbol                                                                                                 | Parameter               | Test conditions                 | Min. | Typ. | Max. | Unit          |
| INPUT characteristics                                                                                  |                         |                                 |      |      |      |               |
| $V_{\text{IL}}$                                                                                        | Input low level voltage |                                 |      |      | 0.9  | $\text{V}$    |
| $I_{\text{IL}}$                                                                                        | Low level input current | $V_{\text{IN}} = 0.9 \text{ V}$ | 1    |      |      | $\mu\text{A}$ |

| 7 V < V <sub>CC</sub> < 28 V; -40°C < T <sub>j</sub> < 150°C                      |                          |                         |      |      |      |      |
|-----------------------------------------------------------------------------------|--------------------------|-------------------------|------|------|------|------|
| Symbol                                                                            | Parameter                | Test conditions         | Min. | Typ. | Max. | Unit |
| V <sub>IH</sub>                                                                   | Input high level voltage |                         | 2.1  |      |      | V    |
| I <sub>IH</sub>                                                                   | High level input current | V <sub>IN</sub> = 2.1 V |      |      | 10   | μA   |
| V <sub>I(hyst)</sub>                                                              | Input hysteresis voltage |                         | 0.2  |      |      | V    |
| V <sub>ICL</sub>                                                                  | Input clamp voltage      | I <sub>IN</sub> = 1 mA  | 5.3  |      | 7.2  | V    |
|                                                                                   |                          | I <sub>IN</sub> = -1 mA |      | -0.7 |      |      |
| FaultRST characteristics (VN7040AJ only)                                          |                          |                         |      |      |      |      |
| V <sub>FRL</sub>                                                                  | Input low level voltage  |                         |      |      | 0.9  | V    |
| I <sub>FRL</sub>                                                                  | Low level input current  | V <sub>IN</sub> = 0.9 V | 1    |      |      | μA   |
| V <sub>FRH</sub>                                                                  | Input high level voltage |                         | 2.1  |      |      | V    |
| I <sub>FRH</sub>                                                                  | High level input current | V <sub>IN</sub> = 2.1 V |      |      | 10   | μA   |
| V <sub>FR(hyst)</sub>                                                             | Input hysteresis voltage |                         | 0.2  |      |      | V    |
| V <sub>FRCL</sub>                                                                 | Input clamp voltage      | I <sub>IN</sub> = 1 mA  | 5.3  |      | 7.5  | V    |
|                                                                                   |                          | I <sub>IN</sub> = -1 mA |      | -0.7 |      |      |
| SEL <sub>0,1</sub> characteristics (7 V < V <sub>CC</sub> < 18 V) (VN7040AJ only) |                          |                         |      |      |      |      |
| V <sub>SELL</sub>                                                                 | Input low level voltage  |                         |      |      | 0.9  | V    |
| I <sub>SELL</sub>                                                                 | Low level input current  | V <sub>IN</sub> = 0.9 V | 1    |      |      | μA   |
| V <sub>SELH</sub>                                                                 | Input high level voltage |                         | 2.1  |      |      | V    |
| I <sub>SELH</sub>                                                                 | High level input current | V <sub>IN</sub> = 2.1 V |      |      | 10   | μA   |
| V <sub>SEL(hyst)</sub>                                                            | Input hysteresis voltage |                         | 0.2  |      |      | V    |
| V <sub>SELCL</sub>                                                                | Input clamp voltage      | I <sub>IN</sub> = 1 mA  | 5.3  |      | 7.2  | V    |
|                                                                                   |                          | I <sub>IN</sub> = -1 mA |      | -0.7 |      |      |
| SEn characteristics (7 V < V <sub>CC</sub> < 18 V)                                |                          |                         |      |      |      |      |
| V <sub>SEnL</sub>                                                                 | Input low level voltage  |                         |      |      | 0.9  | V    |
| I <sub>SEnL</sub>                                                                 | Low level input current  | V <sub>IN</sub> = 0.9 V | 1    |      |      | μA   |
| V <sub>SEnH</sub>                                                                 | Input high level voltage |                         | 2.1  |      |      | V    |
| I <sub>SEnH</sub>                                                                 | High level input current | V <sub>IN</sub> = 2.1 V |      |      | 10   | μA   |
| V <sub>SEn(hyst)</sub>                                                            | Input hysteresis voltage |                         | 0.2  |      |      | V    |
| V <sub>SEnCL</sub>                                                                | Input clamp voltage      | I <sub>IN</sub> = 1 mA  | 5.3  |      | 7.2  | V    |
|                                                                                   |                          | I <sub>IN</sub> = -1 mA |      | -0.7 |      |      |

**Table 8. Protections**

| 7 V < V <sub>CC</sub> < 18 V; -40°C < T <sub>j</sub> < 150°C |                                                                        |                                                                                                                                  |                      |                      |                      |      |
|--------------------------------------------------------------|------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------|----------------------|----------------------|----------------------|------|
| Symbol                                                       | Parameter                                                              | Test conditions                                                                                                                  | Min.                 | Typ.                 | Max.                 | Unit |
| I <sub>LIMH</sub>                                            | DC short circuit current                                               | V <sub>CC</sub> = 13 V                                                                                                           | 24                   | 34                   | 48                   | A    |
|                                                              |                                                                        | 4 V < V <sub>CC</sub> < 18 V <sup>(1)</sup>                                                                                      |                      |                      |                      |      |
| I <sub>LIML</sub>                                            | Short circuit current during thermal cycling                           | V <sub>CC</sub> = 13 V;<br>T <sub>R</sub> < T <sub>j</sub> < T <sub>TSD</sub>                                                    |                      | 13                   |                      |      |
| T <sub>TSD</sub>                                             | Shutdown temperature                                                   |                                                                                                                                  | 150                  | 175                  | 200                  | °C   |
| T <sub>R</sub>                                               | Reset temperature <sup>(1)</sup>                                       |                                                                                                                                  | T <sub>RS</sub> + 1  | T <sub>RS</sub> + 7  |                      |      |
| T <sub>RS</sub>                                              | Thermal reset of fault diagnostic indication                           | V <sub>FR</sub> = 0 V; V <sub>SEn</sub> = 5 V                                                                                    | 135                  |                      |                      |      |
| T <sub>HYST</sub>                                            | Thermal hysteresis(T <sub>TSD</sub> - T <sub>R</sub> ) <sup>(1)</sup>  |                                                                                                                                  |                      | 7                    |                      |      |
| ΔT <sub>J_SD</sub>                                           | Dynamic temperature                                                    | T <sub>j</sub> = -40°C; V <sub>CC</sub> = 13 V                                                                                   |                      | 60                   |                      | K    |
| t <sub>LATCH_RST</sub>                                       | Fault reset time for output unlatch (only for VN7040AJ) <sup>(1)</sup> | V <sub>FR</sub> = 5 V to 0 V; V <sub>SEn</sub> = 5 V;<br>V <sub>IN</sub> = 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 0 V | 3                    | 10                   | 20                   | μs   |
| V <sub>DEMAG</sub>                                           | Turn-off output voltage clamp                                          | I <sub>OUT</sub> = 2 A; L = 6 mH; T <sub>j</sub> = -40°C                                                                         | V <sub>CC</sub> - 38 |                      |                      | V    |
|                                                              |                                                                        | I <sub>OUT</sub> = 2 A; L = 6 mH; T <sub>j</sub> = 25°C to 150°C                                                                 | V <sub>CC</sub> - 41 | V <sub>CC</sub> - 46 | V <sub>CC</sub> - 52 | V    |
| V <sub>ON</sub>                                              | Output voltage drop limitation                                         | I <sub>OUT</sub> = 0.25 A                                                                                                        |                      | 20                   |                      | mV   |

1. Parameter guaranteed by design and characterization; not subjected to production test.

**Table 9. MultiSense**

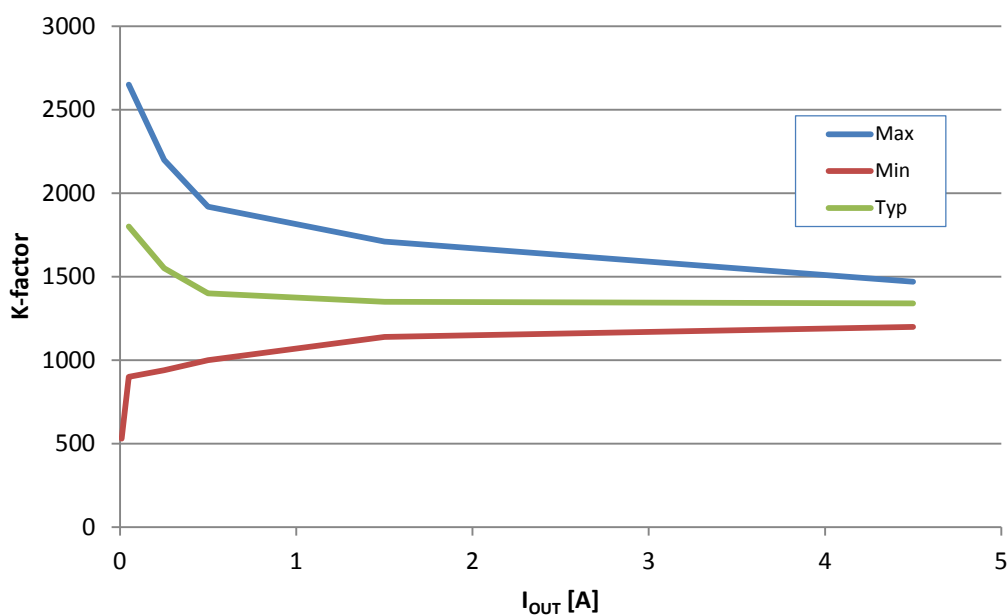
| 7 V < V <sub>CC</sub> < 18 V; -40°C < T <sub>J</sub> < 150°C |                                                |                                                                                                                      |      |      |      |      |
|--------------------------------------------------------------|------------------------------------------------|----------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| Symbol                                                       | Parameter                                      | Test conditions                                                                                                      | Min. | Typ. | Max. | Unit |
| V <sub>SENSE_CL</sub>                                        | MultiSense clamp voltage                       | V <sub>SEn</sub> = 0 V; I <sub>SENSE</sub> = 1 mA                                                                    | -17  |      | -12  | V    |
|                                                              |                                                | V <sub>SEn</sub> = 0 V; I <sub>SENSE</sub> = -1 mA                                                                   |      | 7    |      |      |
| CurrentSense characteristics                                 |                                                |                                                                                                                      |      |      |      |      |
| K <sub>OL</sub>                                              | I <sub>OUT</sub> /I <sub>SENSE</sub>           | I <sub>OUT</sub> = 0.01 A; V <sub>SENSE</sub> = 0.5 V;<br>V <sub>SEn</sub> = 5 V                                     | 530  |      |      |      |
| dK <sub>cal</sub> /K <sub>cal</sub> <sup>(1) (2)</sup>       | Current sense ratio drift at calibration point | I <sub>OUT</sub> = 0.01 A to 0.03 A; I <sub>cal</sub> = 30 mA;<br>V <sub>SENSE</sub> = 0.5 V; V <sub>SEn</sub> = 5 V | -30  |      | 30   | %    |
| K <sub>LED</sub>                                             | I <sub>OUT</sub> /I <sub>SENSE</sub>           | I <sub>OUT</sub> = 0.05 A; V <sub>SENSE</sub> = 0.5 V;<br>V <sub>SEn</sub> = 5 V                                     | 900  | 1800 | 2650 |      |
| dK <sub>LED</sub> /K <sub>LED</sub> <sup>(1) (2)</sup>       | Current sense ratio drift                      | I <sub>OUT</sub> = 0.05 A; V <sub>SENSE</sub> = 0.5 V;<br>V <sub>SEn</sub> = 5 V                                     | -25  |      | 25   | %    |
| K <sub>0</sub>                                               | I <sub>OUT</sub> /I <sub>SENSE</sub>           | I <sub>OUT</sub> = 0.25 A; V <sub>SENSE</sub> = 0.5 V;<br>V <sub>SEn</sub> = 5 V                                     | 940  | 1550 | 2200 |      |
| dK <sub>0</sub> /K <sub>0</sub> <sup>(1) (2)</sup>           | Current sense ratio drift                      | I <sub>OUT</sub> = 0.25 A; V <sub>SENSE</sub> = 0.5 V;<br>V <sub>SEn</sub> = 5 V                                     | -20  |      | 20   | %    |
| K <sub>1</sub>                                               | I <sub>OUT</sub> /I <sub>SENSE</sub>           | I <sub>OUT</sub> = 0.5 A; V <sub>SENSE</sub> = 4 V;<br>V <sub>SEn</sub> = 5 V                                        | 1000 | 1400 | 1920 |      |

| 7 V < V <sub>CC</sub> < 18 V; -40°C < T <sub>j</sub> < 150°C |                                                                                                         |                                                                                                                                                                                                               |      |      |      |      |
|--------------------------------------------------------------|---------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| Symbol                                                       | Parameter                                                                                               | Test conditions                                                                                                                                                                                               | Min. | Typ. | Max. | Unit |
| dK <sub>1</sub> /K <sub>1</sub> <sup>(1) (2)</sup>           | Current sense ratio drift                                                                               | I <sub>OUT</sub> = 0.5 A; V <sub>SENSE</sub> = 4 V;<br>V <sub>SEn</sub> = 5 V                                                                                                                                 | -15  |      | 15   | %    |
| K <sub>2</sub>                                               | I <sub>OUT</sub> /I <sub>SENSE</sub>                                                                    | I <sub>OUT</sub> = 1.5 A; V <sub>SENSE</sub> = 4 V;<br>V <sub>SEn</sub> = 5 V                                                                                                                                 | 1140 | 1350 | 1710 |      |
| dK <sub>2</sub> /K <sub>2</sub> <sup>(1) (2)</sup>           | Current sense ratio drift                                                                               | I <sub>OUT</sub> = 1.5 A; V <sub>SENSE</sub> = 4 V;<br>V <sub>SEn</sub> = 5 V                                                                                                                                 | -10  |      | 10   | %    |
| K <sub>3</sub>                                               | I <sub>OUT</sub> /I <sub>SENSE</sub>                                                                    | I <sub>OUT</sub> = 4.5 A; V <sub>SENSE</sub> = 4 V;<br>V <sub>SEn</sub> = 5 V                                                                                                                                 | 1200 | 1340 | 1470 |      |
| dK <sub>3</sub> /K <sub>3</sub> <sup>(1) (2)</sup>           | Current sense ratio drift                                                                               | I <sub>OUT</sub> = 4.5 A; V <sub>SENSE</sub> = 4 V;<br>V <sub>SEn</sub> = 5 V                                                                                                                                 | -5   |      | 5    | %    |
| I <sub>SENSE0</sub>                                          | MultiSense leakage current                                                                              | MultiSense disabled: V <sub>SEn</sub> = 0 V                                                                                                                                                                   | 0    |      | 0.5  | μA   |
|                                                              |                                                                                                         | MultiSense disabled:<br>-1 V < V <sub>SENSE</sub> < 5 V <sup>(1)</sup>                                                                                                                                        | -0.5 |      | 0.5  |      |
|                                                              |                                                                                                         | MultiSense enabled: V <sub>SEn</sub> = 5 V;<br>Channel ON; I <sub>OUT</sub> = 0 A; Diagnostic<br>selected; V <sub>IN</sub> = 5 V; V <sub>SEL0</sub> = 0 V;<br>V <sub>SEL1</sub> = 0 V; I <sub>OUT</sub> = 0 A | 0    |      | 2    |      |
|                                                              |                                                                                                         | MultiSense enabled: V <sub>SEn</sub> = 5 V;<br>Channel OFF; Diagnostic selected:<br>V <sub>IN</sub> = 0 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 0 V                                                   | 0    |      | 2    |      |
| V <sub>OUT_MSD</sub> <sup>(1)</sup>                          | Output voltage for MultiSense<br>shutdown                                                               | V <sub>IN</sub> = 5 V; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V;<br>V <sub>SEL1</sub> = 0 V; R <sub>SENSE</sub> = 2.7 kΩ;<br>I <sub>OUT</sub> = 2.5 A                                                  |      | 5    |      | V    |
| V <sub>SENSE_SAT</sub>                                       | Multisense saturation voltage                                                                           | V <sub>CC</sub> = 7 V; R <sub>SENSE</sub> = 2.7 kΩ;<br>V <sub>SEn</sub> = 5 V; V <sub>IN</sub> = 5 V; V <sub>SEL0</sub> = 0 V;<br>V <sub>SEL1</sub> = 0 V; I <sub>OUT</sub> = 4.5 A; T <sub>j</sub> = 150°C   | 5    |      |      | V    |
| I <sub>SENSE_SAT</sub> <sup>(1)</sup>                        | CS saturation current                                                                                   | V <sub>CC</sub> = 7 V; V <sub>SENSE</sub> = 4 V; V <sub>IN</sub> = 5 V;<br>V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 0 V;<br>T <sub>j</sub> = 150°C                                | 4    |      |      | mA   |
| I <sub>OUT_SAT</sub> <sup>(1)</sup>                          | Output saturation current                                                                               | V <sub>CC</sub> = 7 V; V <sub>SENSE</sub> = 4 V; V <sub>IN</sub> = 5 V;<br>V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 0 V;<br>T <sub>j</sub> = 150°C                                | 6    |      |      | A    |
| OFF-state diagnostic                                         |                                                                                                         |                                                                                                                                                                                                               |      |      |      |      |
| V <sub>OL</sub>                                              | OFF-state open-load voltage<br>detection threshold                                                      | V <sub>IN</sub> = 0 V; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V;<br>V <sub>SEL1</sub> = 0 V                                                                                                            | 2    | 3    | 4    | V    |
| I <sub>L(off2)</sub>                                         | OFF-state output sink current                                                                           | V <sub>IN</sub> = 0 V; V <sub>OUT</sub> = V <sub>OL</sub>                                                                                                                                                     | -100 |      | -15  | μA   |
| t <sub>DSTKON</sub>                                          | OFF-state diagnostic delay<br>time from falling edge of<br>INPUT (see )Figure<br>9. T <sub>DSTKON</sub> | V <sub>IN</sub> = 5 V to 0 V; V <sub>SEn</sub> = 5 V;<br>V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 0 V; I <sub>OUT</sub> = 0 A;<br>V <sub>OUT</sub> = 4 V                                                  | 100  | 350  | 700  | μs   |
| t <sub>D_OL_V</sub>                                          | Settling time for valid OFF-<br>state open load diagnostic<br>indication from rising edge of<br>SEn     | V <sub>IN</sub> = 0 V; V <sub>FR</sub> = 0 V; V <sub>SEL0</sub> = 0 V;<br>V <sub>SEL1</sub> = 0 V; V <sub>OUT</sub> = 4 V; V <sub>SEn</sub> = 0 V<br>to 5 V                                                   |      |      | 60   | μs   |
| t <sub>D_VOL</sub>                                           | OFF-state diagnostic delay<br>time from rising edge of V <sub>OUT</sub>                                 | V <sub>IN</sub> = 0 V; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V;<br>V <sub>SEL1</sub> = 0 V; V <sub>OUT</sub> = 0 V to 4 V                                                                             |      | 5    | 30   | μs   |
| Chip temperature analog feedback (VN7040AJ only)             |                                                                                                         |                                                                                                                                                                                                               |      |      |      |      |

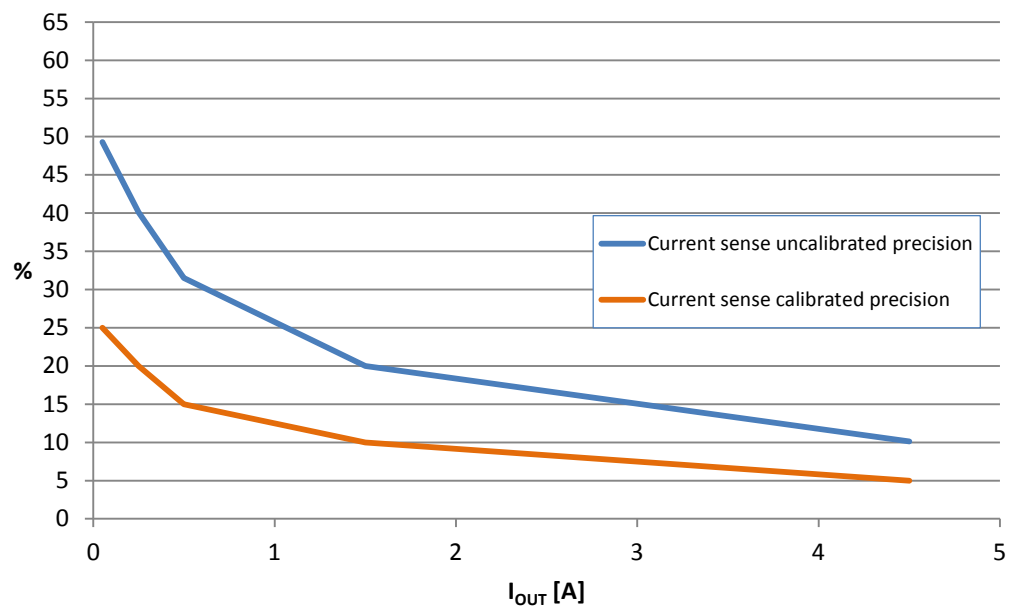
| 7 V < V <sub>CC</sub> < 18 V; -40°C < T <sub>j</sub> < 150°C                                                                                                                |                                                                                                                           |                                                                                                                                                                                                     |       |      |       |      |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|------|-------|------|
| Symbol                                                                                                                                                                      | Parameter                                                                                                                 | Test conditions                                                                                                                                                                                     | Min.  | Typ. | Max.  | Unit |
| V <sub>SENSE_TC</sub>                                                                                                                                                       | MultiSense output voltage proportional to chip temperature                                                                | V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 5 V; V <sub>IN</sub> = 0 V; R <sub>SENSE</sub> = 1 kΩ; T <sub>j</sub> = -40°C                                                  | 2.325 | 2.41 | 2.495 | V    |
|                                                                                                                                                                             |                                                                                                                           | V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 5 V; V <sub>IN</sub> = 0 V; R <sub>SENSE</sub> = 1 kΩ; T <sub>j</sub> = 25°C                                                   | 1.985 | 2.07 | 2.155 | V    |
|                                                                                                                                                                             |                                                                                                                           | V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 5 V; V <sub>IN</sub> = 0 V; R <sub>SENSE</sub> = 1 kΩ; T <sub>j</sub> = 125°C                                                  | 1.435 | 1.52 | 1.605 | V    |
| dV <sub>SENSE_TC</sub> /dT <sup>(1)</sup>                                                                                                                                   | Temperature coefficient                                                                                                   | T <sub>j</sub> = -40°C to 150°C                                                                                                                                                                     |       | -5.5 |       | mV/K |
| Transfer function                                                                                                                                                           |                                                                                                                           | V <sub>SENSE_TC</sub> (T) = V <sub>SENSE_TC</sub> (T <sub>0</sub> ) + dV <sub>SENSE_TC</sub> / dT * (T - T <sub>0</sub> )                                                                           |       |      |       |      |
| V <sub>CC</sub> supply voltage analog feedback (VN7040AJ only)                                                                                                              |                                                                                                                           |                                                                                                                                                                                                     |       |      |       |      |
| V <sub>SENSE_VCC</sub>                                                                                                                                                      | MultiSense output voltage proportional to V <sub>CC</sub> supply voltage                                                  | V <sub>CC</sub> = 13 V; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 5 V; V <sub>SEL1</sub> = 5 V; V <sub>IN</sub> = 0 V; R <sub>SENSE</sub> = 1 kΩ                                                  | 3.16  | 3.23 | 3.3   | V    |
| Transfer function <sup>(3)</sup>                                                                                                                                            |                                                                                                                           | V <sub>SENSE_VCC</sub> = V <sub>CC</sub> / 4                                                                                                                                                        |       |      |       |      |
| Fault diagnostic feedback (see Table 10. Truth table)                                                                                                                       |                                                                                                                           |                                                                                                                                                                                                     |       |      |       |      |
| V <sub>SENSEH</sub>                                                                                                                                                         | MultiSense output voltage in fault condition                                                                              | V <sub>CC</sub> = 13 V; V <sub>IN</sub> = 0 V; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 0 V; I <sub>OUT</sub> = 0 A; V <sub>OUT</sub> = 4 V; R <sub>SENSE</sub> = 1 kΩ; | 5     |      | 6.6   | V    |
| I <sub>SENSEH</sub>                                                                                                                                                         | MultiSense output current in fault condition                                                                              | V <sub>CC</sub> = 13 V; V <sub>SENSE</sub> = 5 V                                                                                                                                                    | 7     | 20   | 30    | mA   |
| MultiSense timings (current sense mode - see Figure 7. MultiSense timings (current sense mode)) <sup>(4)</sup>                                                              |                                                                                                                           |                                                                                                                                                                                                     |       |      |       |      |
| t <sub>DSENSE1H</sub>                                                                                                                                                       | Current sense settling time from rising edge of SEn                                                                       | V <sub>IN</sub> = 5 V; V <sub>SEn</sub> = 0 V to 5 V; R <sub>SENSE</sub> = 1 kΩ; R <sub>L</sub> = 5.2 Ω                                                                                             |       |      | 60    | μs   |
| t <sub>DSENSE1L</sub>                                                                                                                                                       | Current sense disable delay time from falling edge of SEn                                                                 | V <sub>IN</sub> = 5 V; V <sub>SEn</sub> = 5 V to 0 V; R <sub>SENSE</sub> = 1 kΩ; R <sub>L</sub> = 5.2 Ω                                                                                             |       | 5    | 20    | μs   |
| t <sub>DSENSE2H</sub>                                                                                                                                                       | Current sense settling time from rising edge of INPUT                                                                     | V <sub>IN</sub> = 0 V to 5 V; V <sub>SEn</sub> = 5 V; R <sub>SENSE</sub> = 1 kΩ; R <sub>L</sub> = 5.2 Ω                                                                                             |       | 100  | 250   | μs   |
| Δt <sub>DSENSE2H</sub>                                                                                                                                                      | Current sense settling time from rising edge of I <sub>OUT</sub> (dynamic response to a step change of I <sub>OUT</sub> ) | V <sub>IN</sub> = 5 V; V <sub>SEn</sub> = 5 V; R <sub>SENSE</sub> = 1 kΩ; I <sub>SENSE</sub> = 90 % of I <sub>SENSEMAX</sub> ; R <sub>L</sub> = 5.2 Ω                                               |       |      | 100   | μs   |
| t <sub>DSENSE2L</sub>                                                                                                                                                       | Current sense turn-off delay time from falling edge of INPUT                                                              | V <sub>IN</sub> = 5 V to 0 V; V <sub>SEn</sub> = 5 V; R <sub>SENSE</sub> = 1 kΩ; R <sub>L</sub> = 5.2 Ω                                                                                             |       | 50   | 250   | μs   |
| MultiSense timings (chip temperature sense mode - see Figure 8. Multisense timings (chip temperature and V <sub>CC</sub> sense mode) (VN7040AJ only)) <sup>(4)</sup>        |                                                                                                                           |                                                                                                                                                                                                     |       |      |       |      |
| t <sub>DSENSE3H</sub>                                                                                                                                                       | V <sub>SENSE_TC</sub> settling time from rising edge of SEn                                                               | V <sub>SEn</sub> = 0 V to 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 5 V; R <sub>SENSE</sub> = 1 kΩ                                                                                          |       |      | 60    | μs   |
| t <sub>DSENSE3L</sub>                                                                                                                                                       | V <sub>SENSE_TC</sub> disable delay time from falling edge of SEn                                                         | V <sub>SEn</sub> = 5 V to 0 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 5 V; R <sub>SENSE</sub> = 1 kΩ                                                                                          |       |      | 20    | μs   |
| MultiSense timings (V <sub>CC</sub> voltage sense mode - see Figure 8. Multisense timings (chip temperature and V <sub>CC</sub> sense mode) (VN7040AJ only)) <sup>(4)</sup> |                                                                                                                           |                                                                                                                                                                                                     |       |      |       |      |
| t <sub>DSENSE4H</sub>                                                                                                                                                       | V <sub>SENSE_VCC</sub> settling time from rising edge of SEn                                                              | V <sub>SEn</sub> = 0 V to 5 V; V <sub>SEL0</sub> = 5 V; V <sub>SEL1</sub> = 5 V; R <sub>SENSE</sub> = 1 kΩ                                                                                          |       |      | 60    | μs   |
| t <sub>DSENSE4L</sub>                                                                                                                                                       | V <sub>SENSE_VCC</sub> disable delay time from falling edge of SEn                                                        | V <sub>SEn</sub> = 5 V to 0 V; V <sub>SEL0</sub> = 5 V; V <sub>SEL1</sub> = 5 V; R <sub>SENSE</sub> = 1 kΩ                                                                                          |       |      | 20    | μs   |

| 7 V < V <sub>CC</sub> < 18 V; -40°C < T <sub>j</sub> < 150°C                     |                                                                                |                                                                                                                                                              |      |      |      |      |
|----------------------------------------------------------------------------------|--------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|------|
| Symbol                                                                           | Parameter                                                                      | Test conditions                                                                                                                                              | Min. | Typ. | Max. | Unit |
| MultiSense timings (Multiplexer transition times) (VN7040AJ only) <sup>(4)</sup> |                                                                                |                                                                                                                                                              |      |      |      |      |
| t <sub>D_CStoTC</sub>                                                            | MultiSense transition delay from current sense to T <sub>C</sub> sense         | V <sub>IN</sub> = 5 V; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 0 V to 5 V; I <sub>OUT</sub> = 1.25 A; R <sub>SENSE</sub> = 1 kΩ |      |      | 60   | μs   |
| t <sub>D_TCtoCS</sub>                                                            | MultiSense transition delay from T <sub>C</sub> sense to current sense         | V <sub>IN</sub> = 5 V; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V; V <sub>SEL1</sub> = 5 V to 0 V; I <sub>OUT</sub> = 1.25 A; R <sub>SENSE</sub> = 1 kΩ |      |      | 20   | μs   |
| t <sub>D_CStoVCC</sub>                                                           | MultiSense transition delay from current sense to V <sub>CC</sub> sense        | V <sub>IN</sub> = 5 V; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 5 V; V <sub>SEL1</sub> = 0 V to 5 V; I <sub>OUT</sub> = 1.25 A; R <sub>SENSE</sub> = 1 kΩ |      |      | 60   | μs   |
| t <sub>D_VCCtoCS</sub>                                                           | MultiSense transition delay from V <sub>CC</sub> sense to current sense        | V <sub>IN</sub> = 5 V; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 5 V; V <sub>SEL1</sub> = 5 V to 0 V; I <sub>OUT</sub> = 1.25 A; R <sub>SENSE</sub> = 1 kΩ |      |      | 20   | μs   |
| t <sub>D_TCtoVCC</sub>                                                           | MultiSense transition delay from T <sub>C</sub> sense to V <sub>CC</sub> sense | V <sub>CC</sub> = 13 V; T <sub>j</sub> = 125°C; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 0 V to 5 V; V <sub>SEL1</sub> = 5 V; R <sub>SENSE</sub> = 1 kΩ   |      |      | 20   | μs   |
| t <sub>D_VCCtoTC</sub>                                                           | MultiSense transition delay from V <sub>CC</sub> sense to T <sub>C</sub> sense | V <sub>CC</sub> = 13 V; T <sub>j</sub> = 125°C; V <sub>SEn</sub> = 5 V; V <sub>SEL0</sub> = 5 V to 0 V; V <sub>SEL1</sub> = 5 V; R <sub>SENSE</sub> = 1 kΩ   |      |      | 20   | μs   |

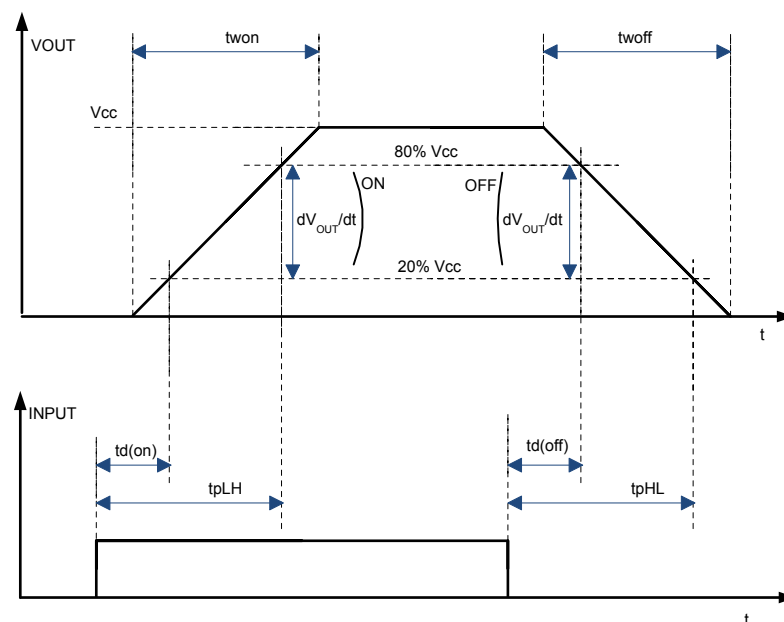
1. Parameter specified by design; not subjected to production test.
2. All values refer to V<sub>CC</sub> = 13 V; T<sub>j</sub> = 25°C, unless otherwise specified.
3. V<sub>CC</sub> sensing and T<sub>C</sub> are referred to GND potential.
4. Transition delays are measured up to +/- 10% of final conditions.

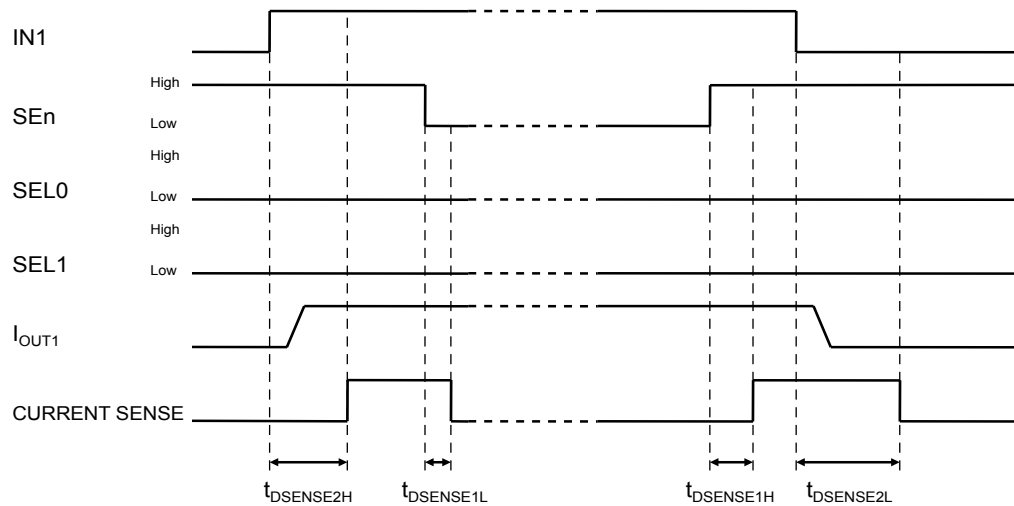
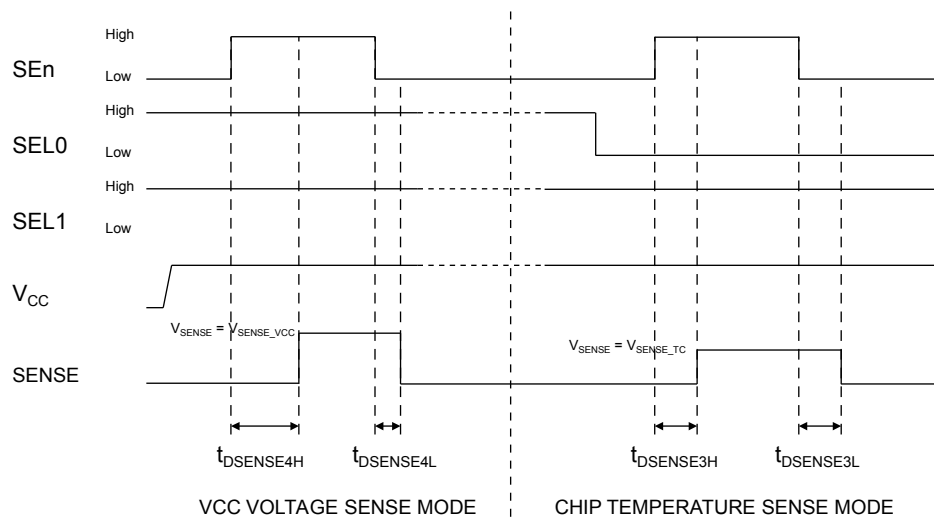
**Figure 4. I<sub>OUT</sub>/I<sub>SENSE</sub> versus I<sub>OUT</sub>**


GAPGCT01210

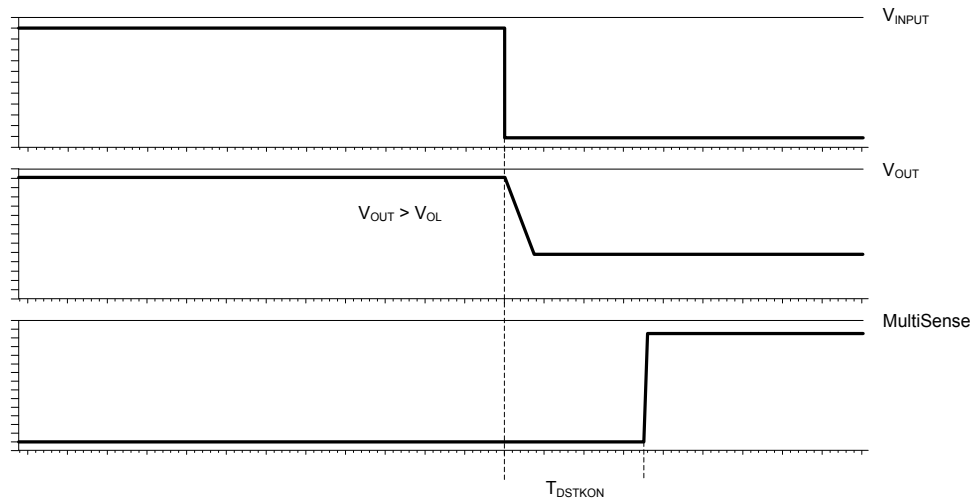
**Figure 5. Current sense accuracy versus  $I_{OUT}$** 


GAPGCF01211

**Figure 6. Switching time and Pulse skew**


**Figure 7. MultiSense timings (current sense mode)**

**Figure 8. Multisense timings (chip temperature and V<sub>CC</sub> sense mode) (VN7040AJ only)**


GAPGCFT00319

**Figure 9.  $T_{DSTKON}$** 


GAPG2609141140CFT

**Table 10. Truth table**

| Mode                    | Conditions                                                                                 | IN <sub>X</sub> | FR <sup>(1)</sup> | SEn                | SEL <sub>X</sub> <sup>(1)</sup> | OUT <sub>X</sub> | MultiSense         | Comments                                                   |
|-------------------------|--------------------------------------------------------------------------------------------|-----------------|-------------------|--------------------|---------------------------------|------------------|--------------------|------------------------------------------------------------|
| Standby                 | All logic inputs low                                                                       | L               | L                 | L                  | L                               | L                | Hi-Z               | Low quiescent current consumption                          |
| Normal                  | Nominal load connected;<br>$T_j < 150\text{ }^{\circ}\text{C}$                             | L               | X                 | See <sup>(2)</sup> |                                 | L                | See <sup>(2)</sup> |                                                            |
|                         |                                                                                            | H               | L                 |                    |                                 | H                | See <sup>(2)</sup> | Outputs configured for auto-restart                        |
|                         |                                                                                            | H               | H                 |                    |                                 | H                | See <sup>(2)</sup> | Outputs configured for latch-off <sup>(1)</sup>            |
| Overload                | Overload or short to GND causing:<br>$T_j > T_{TSD}$ or<br>$\Delta T_j > \Delta T_{j\_SD}$ | L               | X                 | See <sup>(2)</sup> |                                 | L                | See <sup>(2)</sup> |                                                            |
|                         |                                                                                            | H               | L                 |                    |                                 | H                | See <sup>(2)</sup> | Output cycles with temperature hysteresis                  |
|                         |                                                                                            | H               | H                 |                    |                                 | L                | See <sup>(2)</sup> | Output latches-off <sup>(1)</sup>                          |
| Undervoltage            | $V_{CC} < V_{USD}$ (falling)                                                               | X               | X                 | X                  | X                               | L<br>L           | Hi-Z<br>Hi-Z       | Re-start when<br>$V_{CC} > V_{USD} + V_{USDhyst}$ (rising) |
| OFF-state diagnostics   | Short to $V_{CC}$                                                                          | L               | X                 | See <sup>(2)</sup> |                                 | H                | See <sup>(2)</sup> |                                                            |
|                         | Open-load                                                                                  | L               | X                 |                    |                                 | H                | See <sup>(2)</sup> | External pull-up                                           |
| Negative output voltage | Inductive loads turn-off                                                                   | L               | X                 | See <sup>(2)</sup> |                                 | < 0 V            | See <sup>(2)</sup> |                                                            |

1. VN7040AJ only

2. Refer to Table 11. MultiSense multiplexer addressing

**Table 11. MultiSense multiplexer addressing**

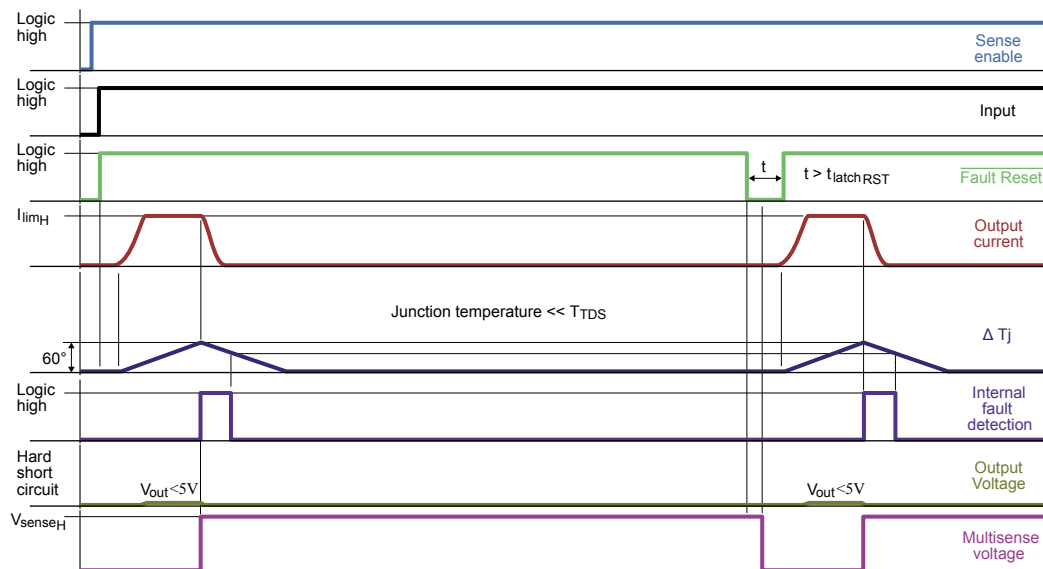
| SEn  | SEL <sub>1</sub> | SEL <sub>0</sub> | MUX channel | MultiSense output |          |                                |                 |
|------|------------------|------------------|-------------|-------------------|----------|--------------------------------|-----------------|
|      |                  |                  |             | Normal mode       | Overload | OFF-state diag. <sup>(1)</sup> | Negative output |
| SO-8 |                  |                  |             |                   |          |                                |                 |

| SEn         | SEL <sub>1</sub> | SEL <sub>0</sub> | MUX channel             | MultiSense output            |                          |                                |                 |
|-------------|------------------|------------------|-------------------------|------------------------------|--------------------------|--------------------------------|-----------------|
|             |                  |                  |                         | Normal mode                  | Overload                 | OFF-state diag. <sup>(1)</sup> | Negative output |
| L           | N.A.             | N.A.             | N.A.                    | Hi-Z                         |                          |                                |                 |
| H           | N.A.             | N.A.             | Channel diagnostic      | $I_{SENSE} = 1/K * I_{OUT}$  | $V_{SENSE} = V_{SENSEH}$ | $V_{SENSE} = V_{SENSEH}$       | Hi-Z            |
| PowerSSO-16 |                  |                  |                         |                              |                          |                                |                 |
| H           | L                | L                | Channel diagnostic      | $I_{SENSE} = 1/K * I_{OUT}$  | $V_{SENSE} = V_{SENSEH}$ | $V_{SENSE} = V_{SENSEH}$       | Hi-Z            |
| H           | L                | H                | Channel diagnostic      | $I_{SENSE} = 1/K * I_{OUT}$  | $V_{SENSE} = V_{SENSEH}$ | $V_{SENSE} = V_{SENSEH}$       | Hi-Z            |
| H           | H                | L                | T <sub>CHIP</sub> Sense | $V_{SENSE} = V_{SENSE\_TC}$  |                          |                                |                 |
| H           | H                | H                | V <sub>CC</sub> Sense   | $V_{SENSE} = V_{SENSE\_VCC}$ |                          |                                |                 |

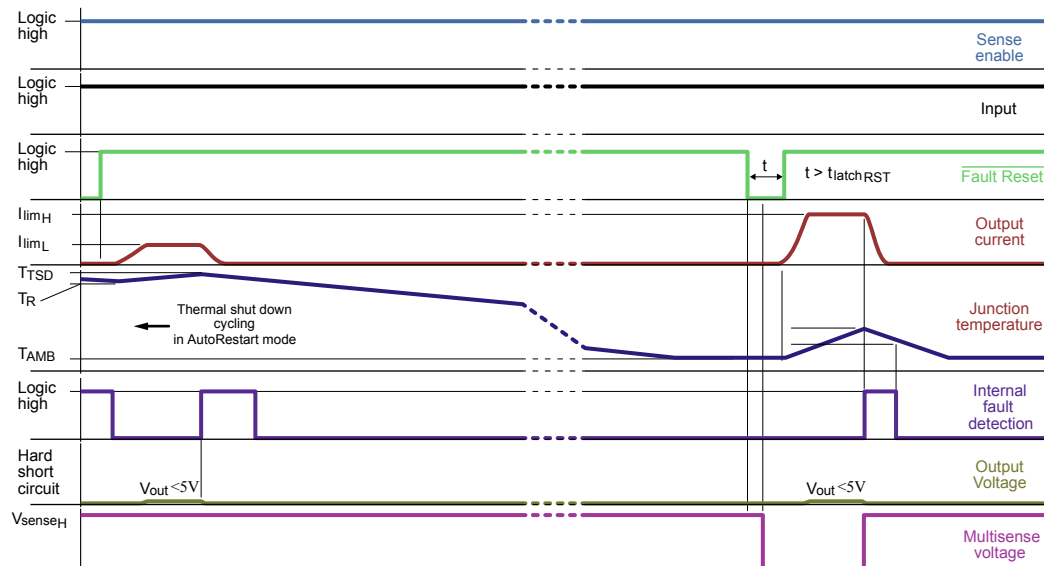
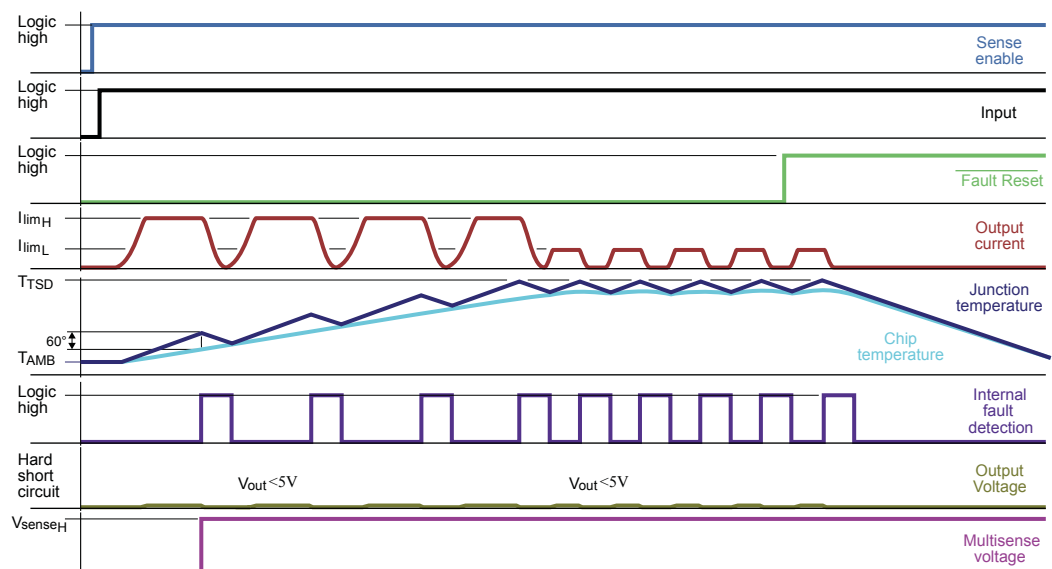
1. In case the output channel corresponding to the selected MUX channel is latched off while the relevant input is low, Multisense pin delivers feedback according to OFF-State diagnostic. Example 1: FR = 1; IN = 0; OUT = L (latched); MUX channel = channel 0 diagnostic; Mutisense = 0. Example 2: FR = 1; IN = 0; OUT = latched,  $V_{OUT} > V_{OL}$ ; MUX channel = channel 0 diagnostic; Mutisense =  $V_{SENSEH}$

## 2.4 Waveforms

**Figure 10. Latch functionality - behavior in hard short-circuit condition ( $T_{AMB} \ll T_{TDS}$ )**

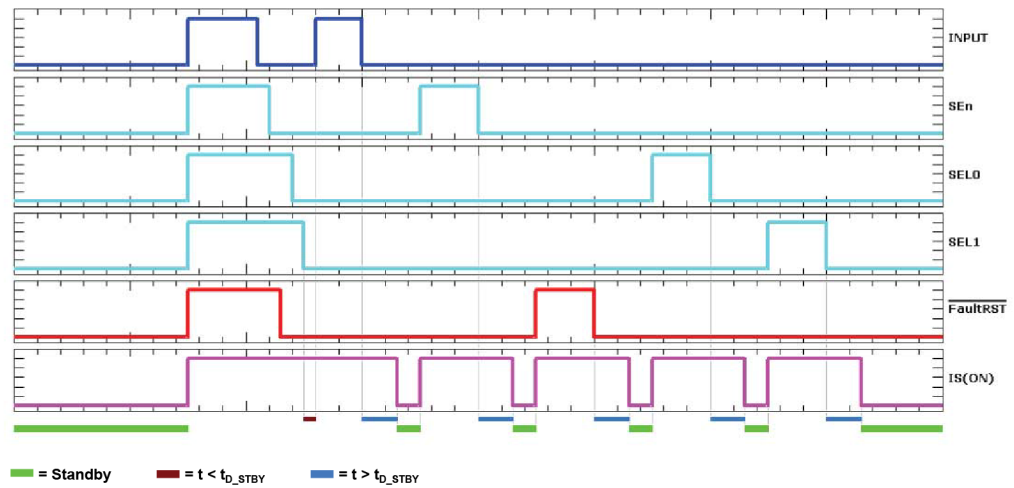


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**Figure 11. Latch functionality - behavior in hard short-circuit condition**

**Figure 12. Latch functionality - behavior in hard short-circuit condition (autorestart mode + latch off)**


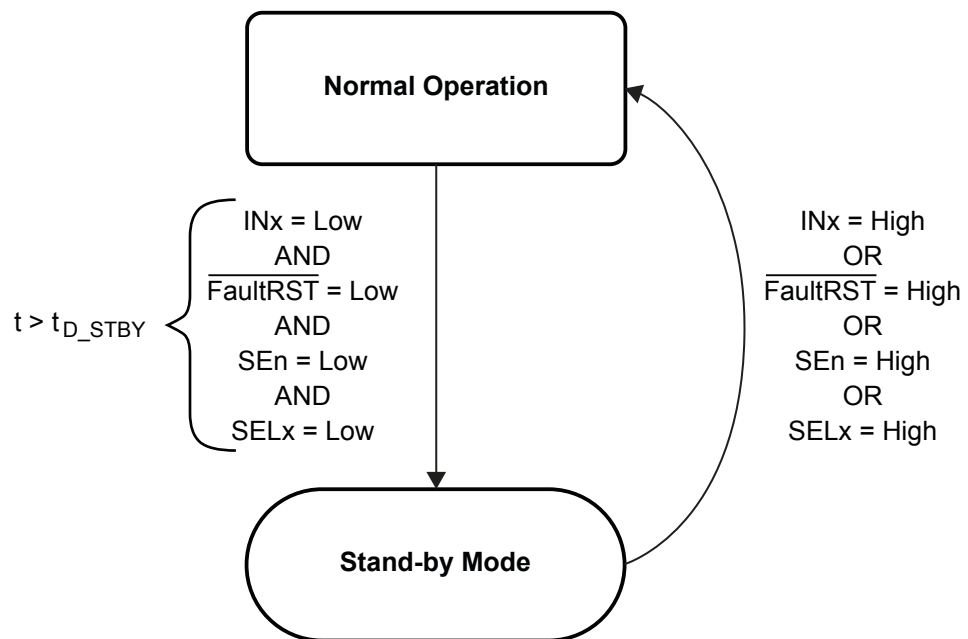
GADG2103171742PS

Figure 13. Standby mode activation



GAPGCFG00793

Figure 14. Standby state diagram



GAPGCF00598

## 2.5 Electrical characteristics curves

Figure 15. OFF-state output current

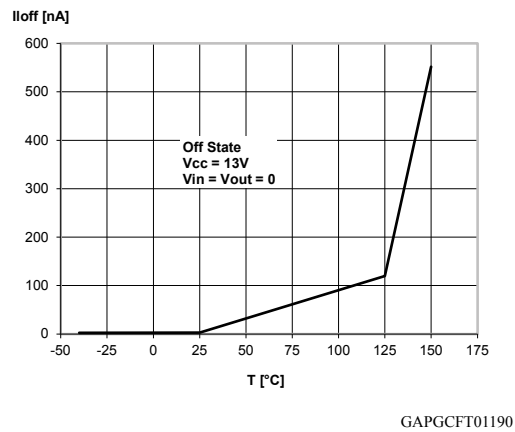


Figure 16. Standby current

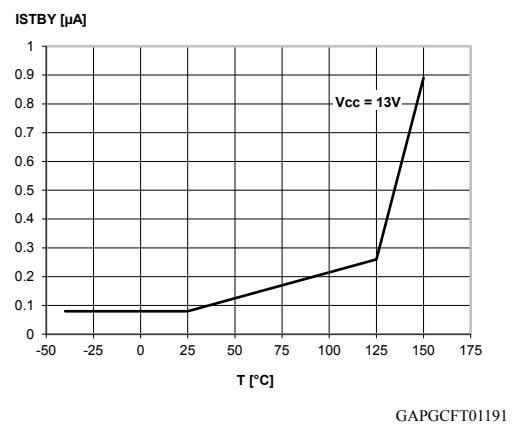


Figure 17.  $I_{GND(ON)}$  vs.  $T_{case}$

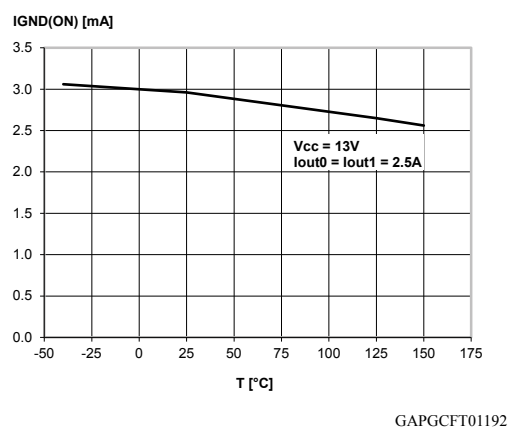


Figure 18. Logic Input high level voltage

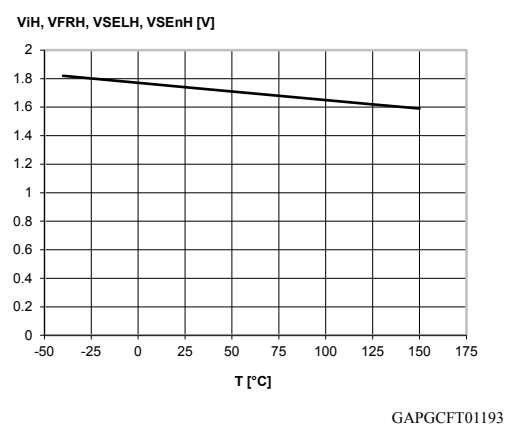
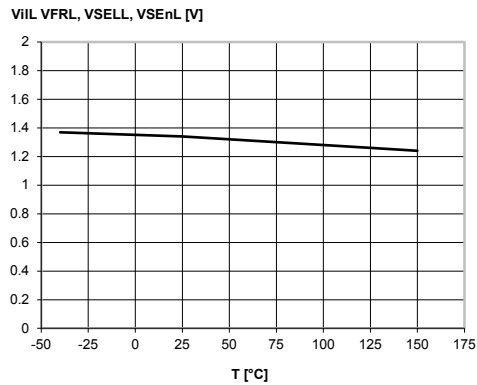
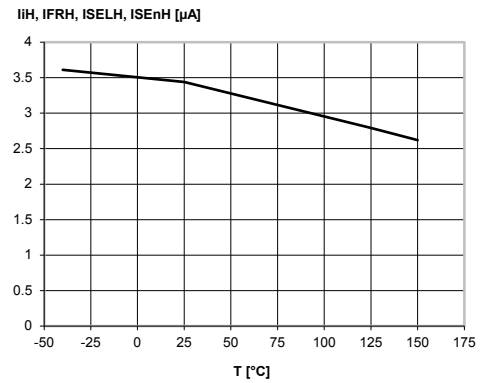


Figure 19. Logic Input low level voltage



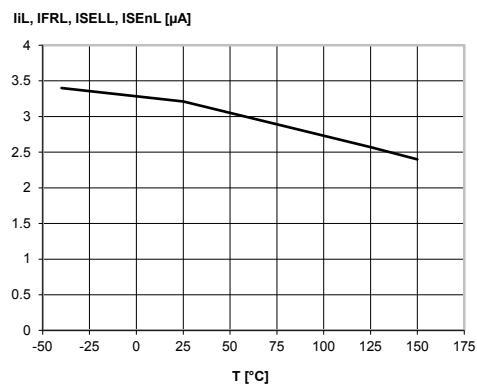
GAPGCFT01194

Figure 20. High level logic input current



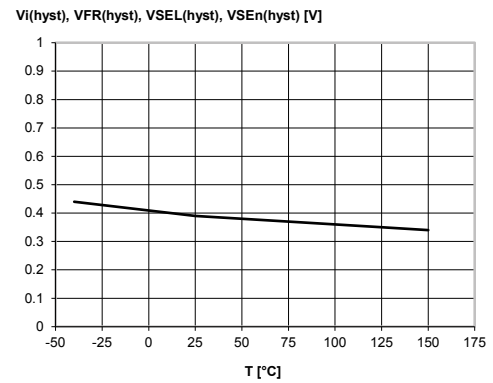
GAPGCFT01195

Figure 21. Low level logic input current



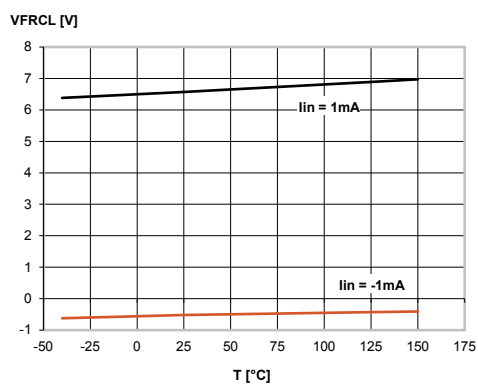
GAPGCFT01196

Figure 22. Logic Input hysteresis voltage



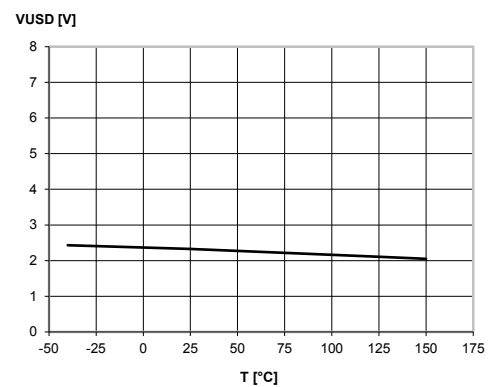
GAPGCFT01197

Figure 23. FaultRST Input clamp voltage



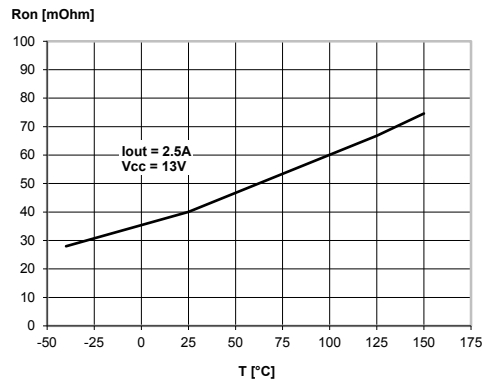
GAPGCFT01198

Figure 24. Undervoltage shutdown



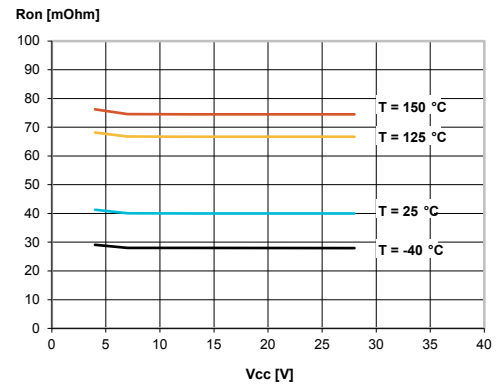
GAPGCFT01199

Figure 25. On-state resistance vs.  $T_{case}$



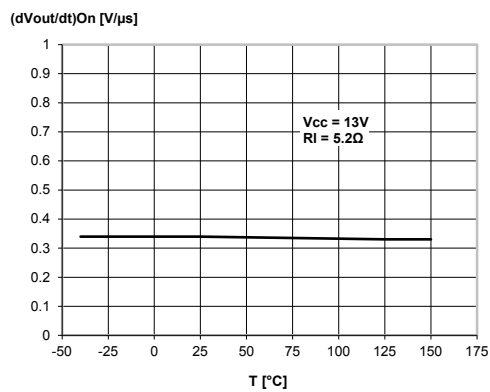
GAPGCFT01200

Figure 26. On-state resistance vs.  $V_{CC}$



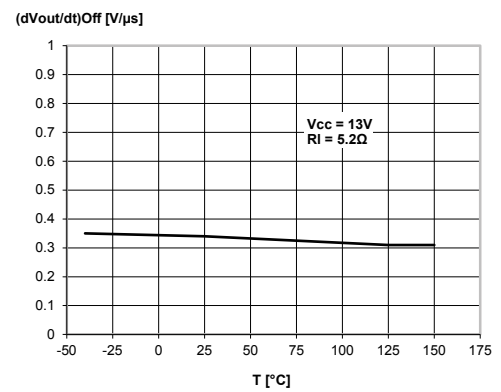
GAPGCFT01201

Figure 27. Turn-on voltage slope



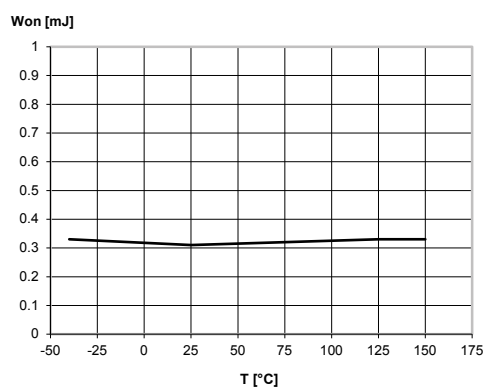
GAPGCFT01202

Figure 28. Turn-off voltage slope



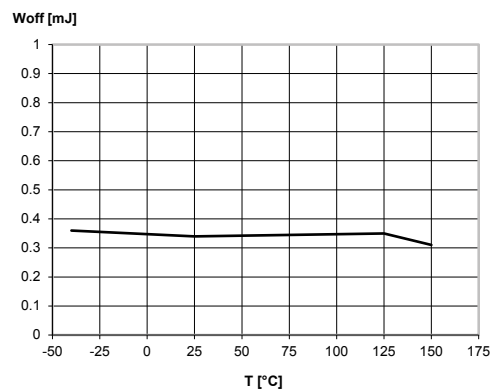
GAPGCFT01203

Figure 29.  $W_{on}$  vs.  $T_{case}$



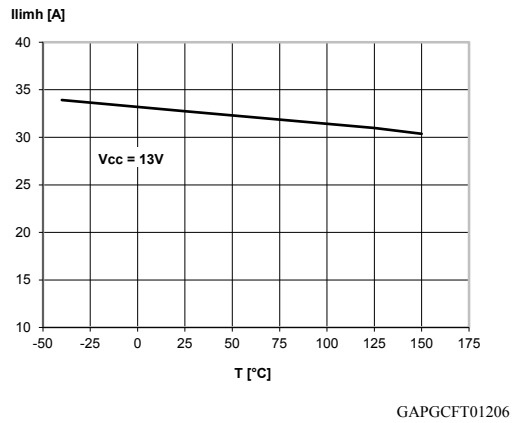
GAPGCFT01204

Figure 30.  $W_{off}$  vs.  $T_{case}$

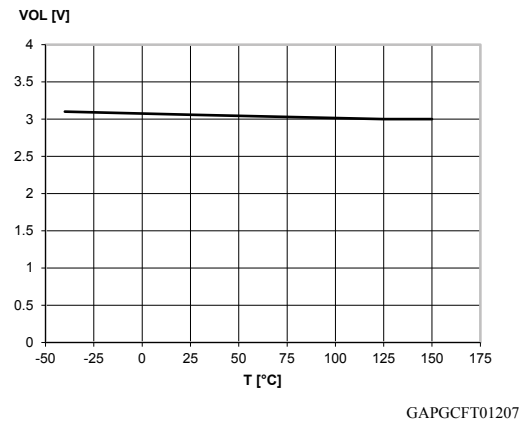


GAPGCFT01205

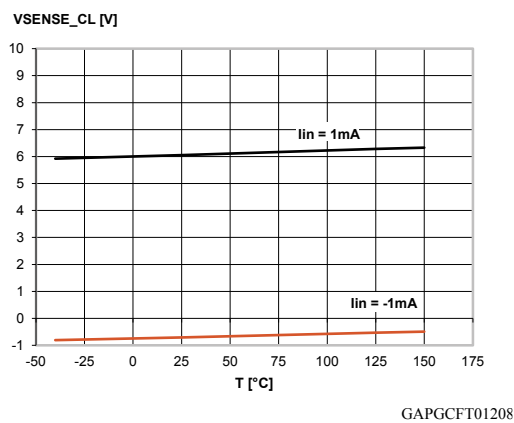
**Figure 31.  $I_{LIMH}$  vs.  $T_{case}$**



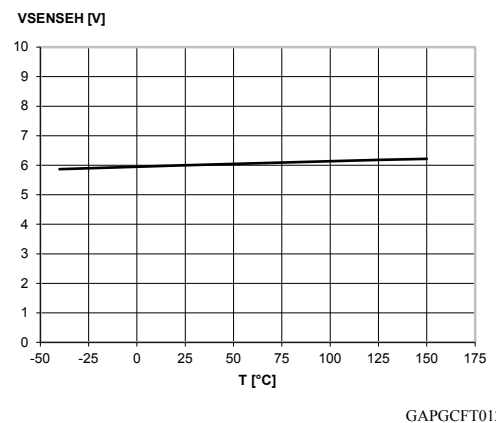
**Figure 32. OFF-state open-load voltage detection threshold**



**Figure 33.  $V_{sense}$  clamp vs.  $T_{case}$**



**Figure 34.  $V_{senseh}$  vs.  $T_{case}$**



## 3 Protections

### 3.1 Power limitation

The basic working principle of this protection consists of an indirect measurement of the junction temperature swing  $\Delta T_j$  through the direct measurement of the spatial temperature gradient on the device surface in order to automatically shut off the output MOSFET as soon as  $\Delta T_j$  exceeds the safety level of  $\Delta T_{j\_SD}$ . According to the voltage level on the FaultRST pin, the output MOSFET switches on and cycles with a thermal hysteresis according to the maximum instantaneous power which can be handled (FaultRST = Low) or remains off (FaultRST = High). The protection prevents fast thermal transient effects and, consequently, reduces thermo-mechanical fatigue.

### 3.2 Thermal shutdown

In case the junction temperature of the device exceeds the maximum allowed threshold (typically 175°C), it automatically switches off and the diagnostic indication is triggered. According to the voltage level on the FaultRST pin, the device switches on again as soon as its junction temperature drops to  $T_R$  (FaultRST = Low) or remains off (FaultRST = High).

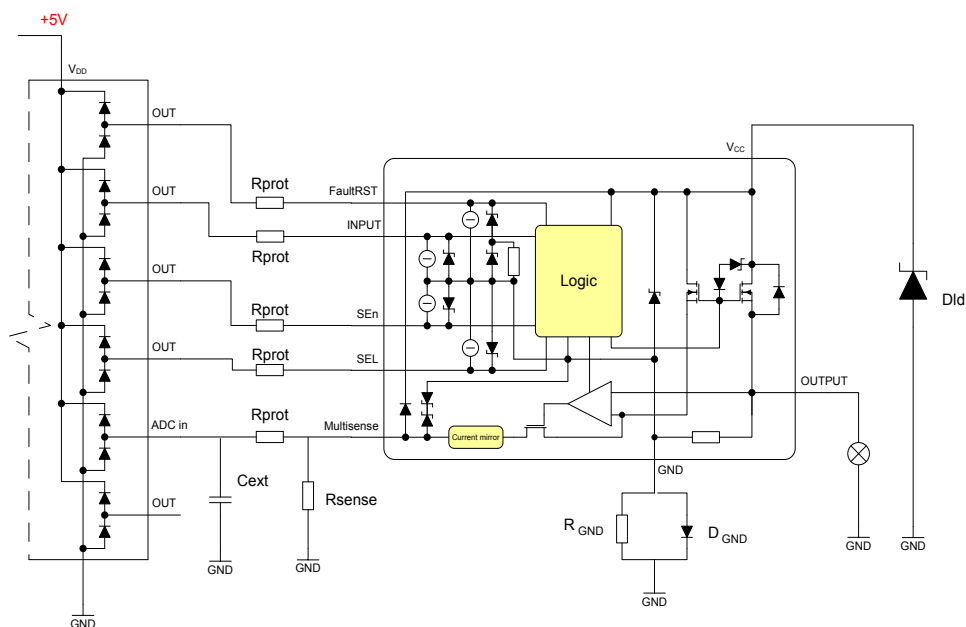
### 3.3 Current limitation

The device is equipped with an output current limiter in order to protect the silicon as well as the other components of the system (e.g. bonding wires, wiring harness, connectors, loads, etc.) from excessive current flow. Consequently, in case of short circuit, overload or during load power-up, the output current is clamped to a safety level,  $I_{LIMH}$ , by operating the output power MOSFET in the active region.

### 3.4 Negative voltage clamp

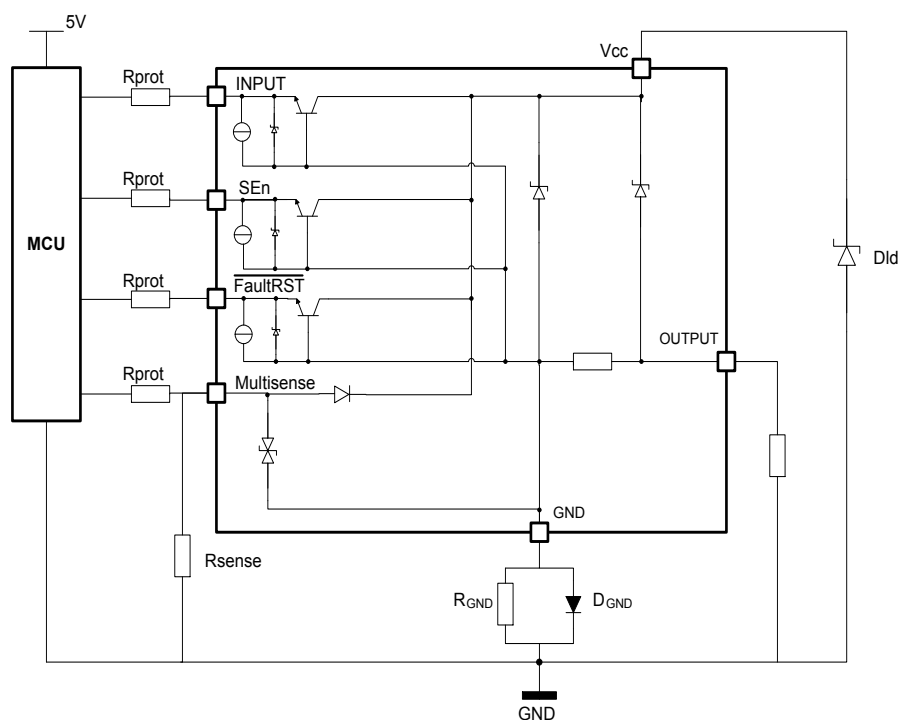
In case the device drives inductive load, the output voltage reaches a negative value during turn off. A negative voltage clamp structure limits the maximum negative voltage to a certain value,  $V_{DEMAG}$ , allowing the inductor energy to be dissipated without damaging the device.

## 4 Application information

**Figure 35. Application diagram**


GAPG0810141031CFT

### 4.1 GND protection network against reverse battery

**Figure 36. Simplified internal structure**


GAPGCF00809

#### 4.1.1 Diode (DGND) in the ground line

A resistor (typ.  $R_{GND} = 4.7 \text{ k}\Omega$ ) should be inserted in parallel to  $D_{GND}$  if the device drives an inductive load.

This small signal diode can be safely shared amongst several different HSDs. Also in this case, the presence of the ground network produces a shift ( $\approx 600 \text{ mV}$ ) in the input threshold and in the status output values if the microprocessor ground is not common to the device ground. This shift does not vary if more than one HSD shares the same diode/resistor network.

## 4.2 Immunity against transient electrical disturbances

The immunity of the device against transient electrical emissions, conducted along the supply lines and injected into the  $V_{CC}$  pin, is tested in accordance with ISO7637-2:2011 (E) and ISO 16750-2:2010.

The related function performance status classification is shown in [Table 12. ISO 7637-2 - electrical transient conduction along supply line](#).

Test pulses are applied directly to DUT (Device Under Test) both in ON and OFF-state and in accordance to ISO 7637-2:2011(E), chapter 4. The DUT is intended as the present device only, without components and accessed through  $V_{CC}$  and GND terminals.

Status II is defined in ISO 7637-1 Function Performance Status Classification (FPSC) as follows: "The function does not perform as designed during the test but returns automatically to normal operation after the test".

**Table 12. ISO 7637-2 - electrical transient conduction along supply line**

| Test Pulse<br>2011(E)                   | Test pulse severity level with<br>Status II functional<br>performance status |             | Minimum number<br>of pulses or test<br>time | Burst cycle / pulse<br>repetition time |        | Pulse duration and pulse<br>generator internal<br>impedance |
|-----------------------------------------|------------------------------------------------------------------------------|-------------|---------------------------------------------|----------------------------------------|--------|-------------------------------------------------------------|
|                                         | Level                                                                        | $U_S^{(1)}$ |                                             | min                                    | max    |                                                             |
| 1                                       | III                                                                          | -112 V      | 500 pulses                                  | 0.5 s                                  |        | 2 ms, 10 $\Omega$                                           |
| 2a                                      | III                                                                          | +55 V       | 500 pulses                                  | 0.2 s                                  | 5 s    | 50 $\mu\text{s}$ , 2 $\Omega$                               |
| 3a                                      | IV                                                                           | -220 V      | 1h                                          | 90 ms                                  | 100 ms | 0.1 $\mu\text{s}$ , 50 $\Omega$                             |
| 3b                                      | IV                                                                           | +150 V      | 1h                                          | 90 ms                                  | 100 ms | 0.1 $\mu\text{s}$ , 50 $\Omega$                             |
| 4 <sup>(2)</sup>                        | IV                                                                           | -7 V        | 1 pulse                                     |                                        |        | 100 ms, 0.01 $\Omega$                                       |
| Load dump according to ISO 16750-2:2010 |                                                                              |             |                                             |                                        |        |                                                             |
| Test B <sup>(3)</sup>                   |                                                                              | 40 V        | 5 pulse                                     | 1 min                                  |        | 400 ms, 2 $\Omega$                                          |

1.  $U_S$  is the peak amplitude as defined for each test pulse in ISO 7637-2:2011(E), chapter 5.6.

2. Test pulse from ISO 7637-2:2004(E).

3. With 40 V external suppressor referred to ground ( $-40^\circ\text{C} < T_J < 150^\circ\text{C}$ ).

## 4.3 MCU I/Os protection

If a ground protection network is used and negative transients are present on the  $V_{CC}$  line, the control pins will be pulled negative. ST suggests to insert a resistor ( $R_{prot}$ ) in line both to prevent the microcontroller I/O pins from latching-up and to protect the HSD inputs.

The value of these resistors is a compromise between the leakage current of microcontroller and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of microcontroller I/Os.

### Equation

$$V_{CCpeak}/I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH} - V_{GND}) / I_{IHmax}$$

Calculation example:

For  $V_{CCpeak} = -150 \text{ V}$ ;  $I_{latchup} \geq 20 \text{ mA}$ ;  $V_{OH\mu C} \geq 4.5 \text{ V}$

$7.5 \text{ k}\Omega \leq R_{prot} \leq 140 \text{ k}\Omega$ .

Recommended values:  $R_{\text{prot}} = 15 \text{ k}\Omega$

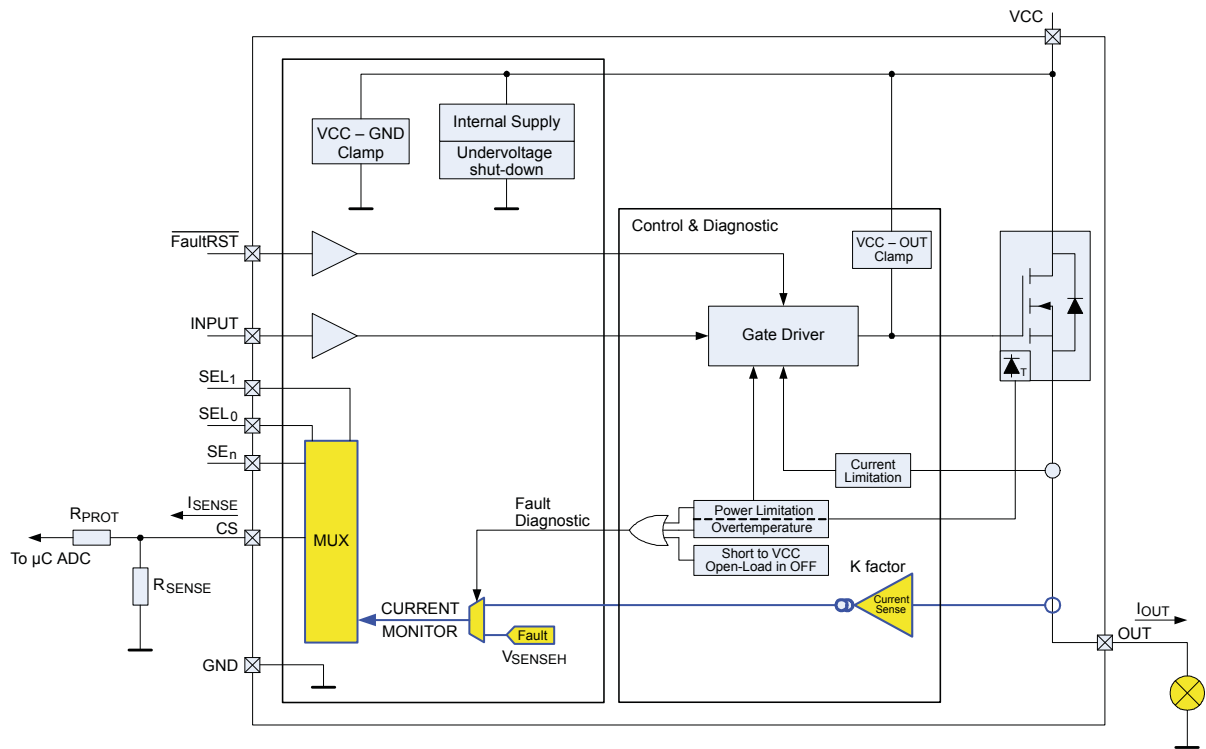
#### 4.4 Multisense - analog current sense

Diagnostic information on device and load status are provided by an analog output pin (MultiSense) delivering the following signals:

- Current monitor: current mirror of channel output current
- $V_{\text{CC}}$  monitor: voltage proportional to  $V_{\text{CC}}$
- $T_{\text{CASE}}$ : voltage proportional to chip temperature

Those signals are routed through an analog multiplexer which is configured and controlled by means of SELx and SEn pins, according to the address map in *MultiSense multiplexer addressing Table*.

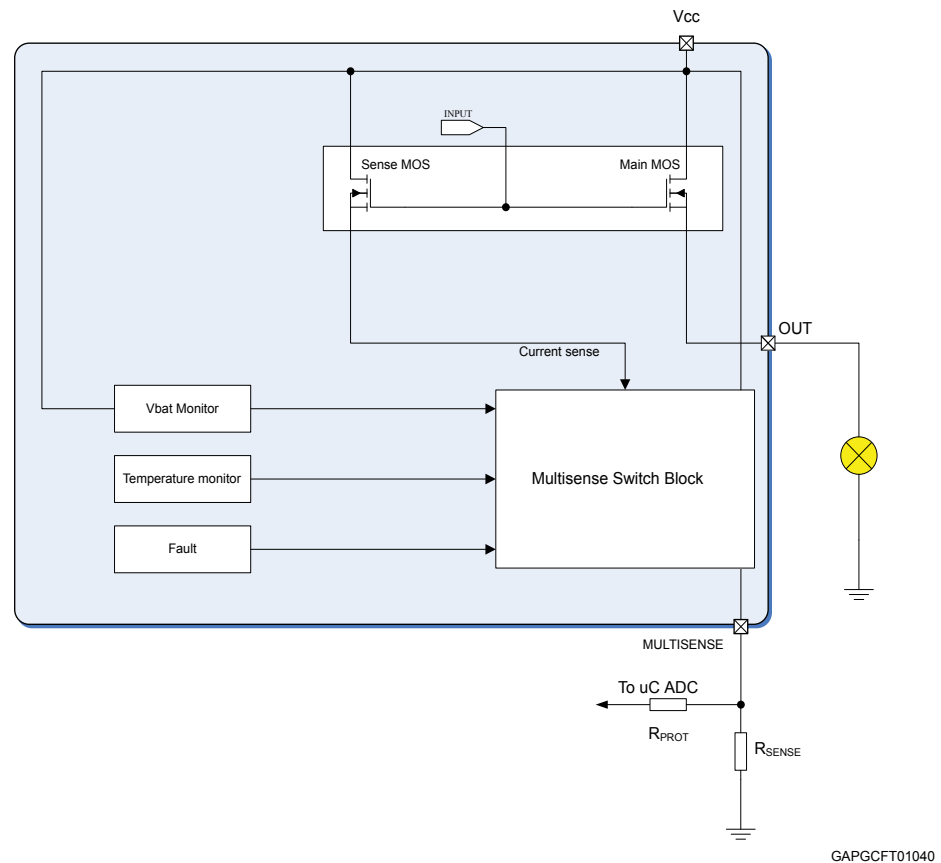
Figure 37. MultiSense and diagnostic – block diagram



GADG2004171456PS

#### 4.4.1 Principle of Multisense signal generation

Figure 38. MultiSense block diagram



##### Current monitor

When current mode is selected in the MultiSense, this output is capable to provide:

- Current mirror proportional to the load current in normal operation, delivering current proportional to the load according to known ratio named **K**
- Diagnostics flag in fault conditions delivering fixed voltage  $V_{SENSEH}$

The current delivered by the current sense circuit,  $I_{SENSE}$ , can be easily converted to a voltage  $V_{SENSE}$  by using an external sense resistor,  $R_{SENSE}$ , allowing continuous load monitoring and abnormal condition detection.

##### Normal operation (channel ON, no fault, SEN active)

While device is operating in normal conditions (no fault intervention),  $V_{SENSE}$  calculation can be done using simple equations

Current provided by MultiSense output:  $I_{SENSE} = I_{OUT}/K$

Voltage on  $R_{SENSE}$ :  $V_{SENSE} = R_{SENSE} \cdot I_{SENSE} = R_{SENSE} \cdot I_{OUT}/K$

Where:

- $V_{SENSE}$  is voltage measurable on  $R_{SENSE}$  resistor
- $I_{SENSE}$  is current provided from MultiSense pin in current output mode
- $I_{OUT}$  is current flowing through output

- K factor represents the ratio between PowerMOS cells and SenseMOS cells; its spread includes geometric factor spread, current sense amplifier offset and process parameters spread of overall circuitry specifying ratio between  $I_{OUT}$  and  $I_{SENSE}$ .

### Failure flag indication

In case of power limitation/overtemperature, the fault is indicated by the MultiSense pin which is switched to a “current limited” voltage source,  $V_{SENSEH}$ .

In any case, the current sourced by the MultiSense in this condition is limited to  $I_{SENSEH}$ .

The typical behavior in case of overload or hard short circuit is shown in *Waveforms* section.

**Figure 39. Analogue HSD – open-load detection in off-state**

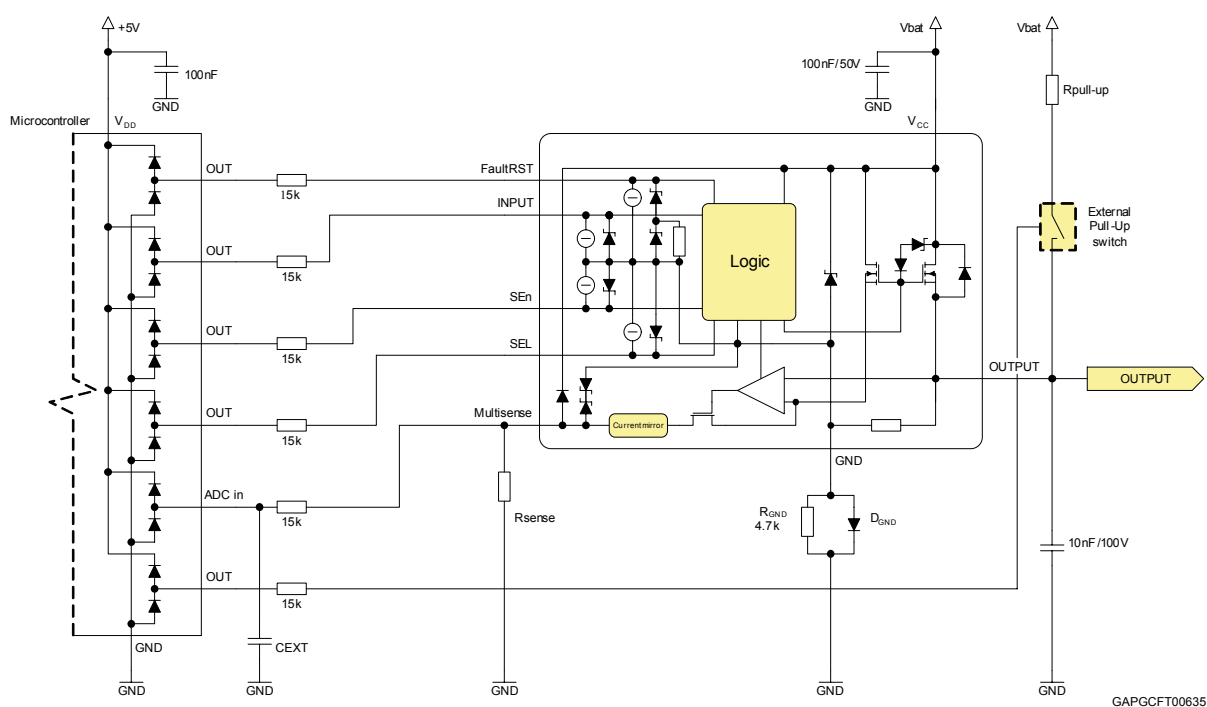


Figure 40. Open-load / short to  $V_{CC}$  condition

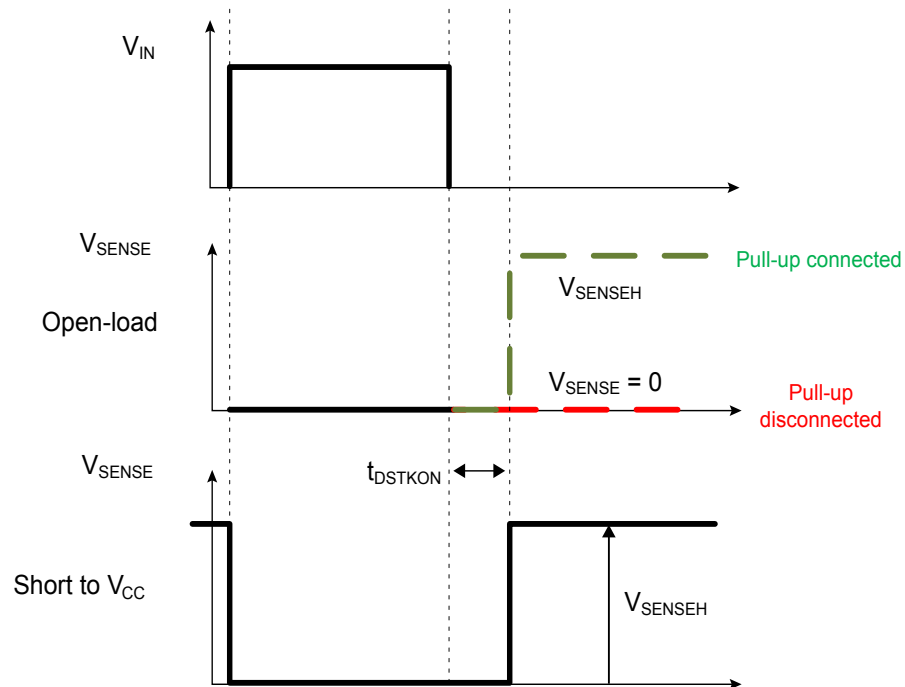


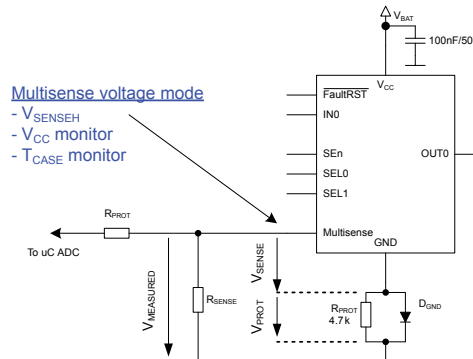
Table 13. MultiSense pin levels in off-state

| Condition         | Output             | MultiSense   | SEn |
|-------------------|--------------------|--------------|-----|
| Open-load         | $V_{OUT} > V_{OL}$ | Hi-Z         | L   |
|                   |                    | $V_{SENSEH}$ | H   |
|                   | $V_{OUT} < V_{OL}$ | Hi-Z         | L   |
|                   |                    | 0            | H   |
| Short to $V_{CC}$ | $V_{OUT} > V_{OL}$ | Hi-Z         | L   |
|                   |                    | $V_{SENSEH}$ | H   |
| Nominal           | $V_{OUT} < V_{OL}$ | Hi-Z         | L   |
|                   |                    | 0            | H   |

#### 4.4.2 TCASE and VCC monitor

In this case, MultiSense output operates in voltage mode and output level is referred to device GND. Care must be taken in case a GND network protection is used, because a voltage shift is generated between the device GND and the microcontroller input GND reference.

Figure 41. GND voltage shift shows the link between  $V_{MEASURED}$  and the real  $V_{SENSE}$  signal.

**Figure 41. GND voltage shift**


GAPGCFT01136

### **$V_{CC}$ monitor**

Battery monitoring channel provides  $V_{SENSE} = V_{CC} / 4$ .

### **Case temperature monitor**

Case temperature monitor is capable of providing information about the actual device temperature. Since a diode is used for temperature sensing, the following equation describes the link between temperature and output  $V_{SENSE}$  level:

$$V_{SENSE\_TC}(T) = V_{SENSE\_TC}(T_0) + dV_{SENSE\_TC} / dT * (T - T_0)$$

where  $dV_{SENSE\_TC} / dT \sim$  typically  $-5.5$  mV/K (for temperature range  $(-40$  °C to  $150$  °C)).

## **4.4.3 Short to $V_{CC}$ and OFF-state open-load detection**

### **Short to $V_{CC}$**

A short circuit between  $V_{CC}$  and output is indicated by the relevant current sense pin set to  $V_{SENSEH}$  during the device off-state. Small or no current is delivered by the current sense during the on-state depending on the nature of the short circuit.

### **OFF-state open-load with external circuitry**

Detection of an open-load in off mode requires an external pull-up resistor  $R_{PU}$  connecting the output to a positive supply voltage  $V_{PU}$ .

It is preferable that  $V_{PU}$  is switched off during the module standby mode in order to avoid the overall standby current consumption to increase in normal conditions, i.e. when load is connected.

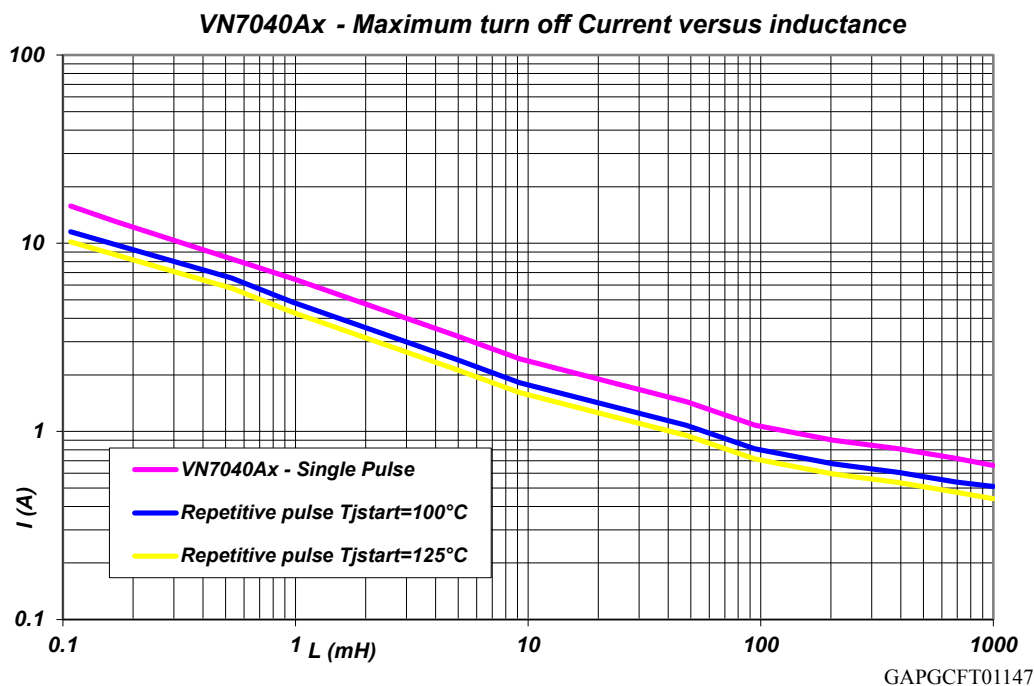
$R_{PU}$  must be selected in order to ensure  $V_{OUT} > V_{OLmax}$  in accordance with the following equation:

### **Equation**

$$R_{PU} < \frac{V_{PU} - 4}{I_{L(off2)min @ 4V}}$$

## 5 Maximum demagnetization energy (VCC = 16 V)

Figure 43. Maximum turn off current versus inductance



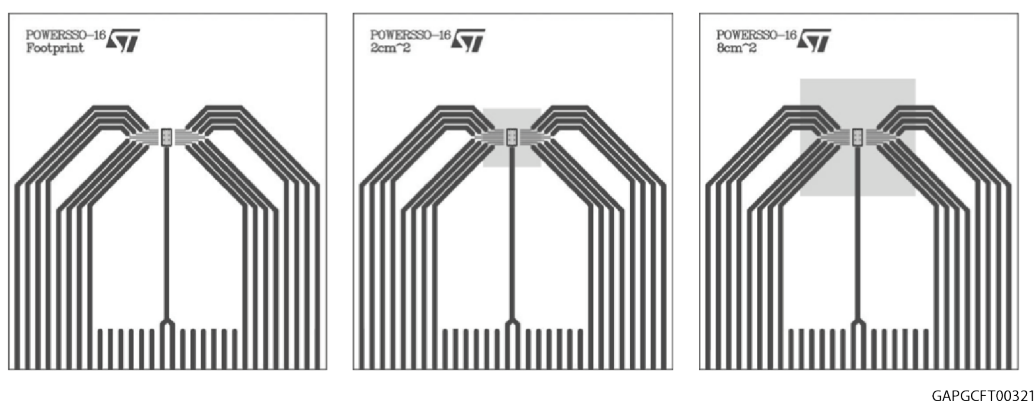
Note: Values are generated with  $R_L = 0 \Omega$ .

In case of repetitive pulses,  $T_{jstart}$  (at the beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves A and B.

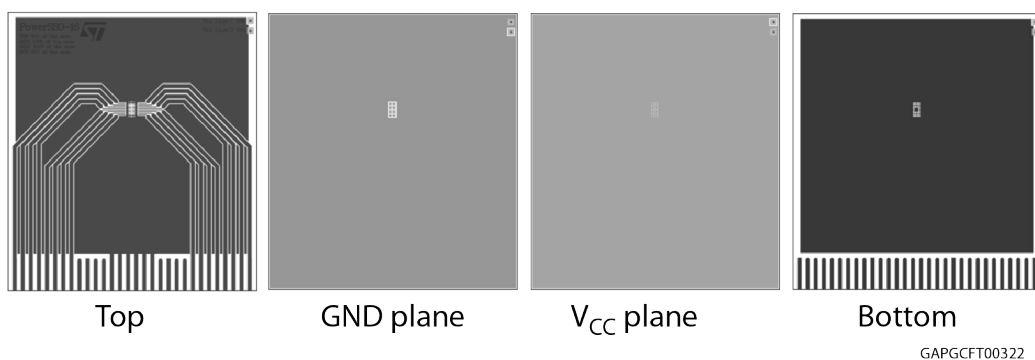
## 6 Package and PCB thermal data

### 6.1 PowerSSO-16 thermal data

**Figure 44. PowerSSO-16 on two-layers PCB (2s0p to JEDEC JESD 51-5)**

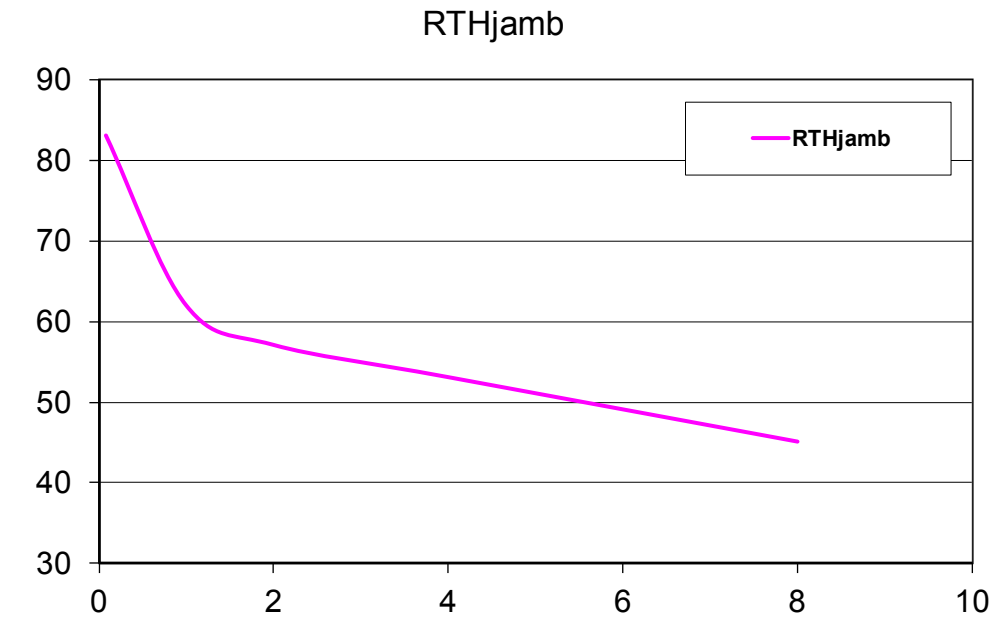


**Figure 45. PowerSSO-16 on four-layers PCB (2s2p to JEDEC JESD 51-7)**



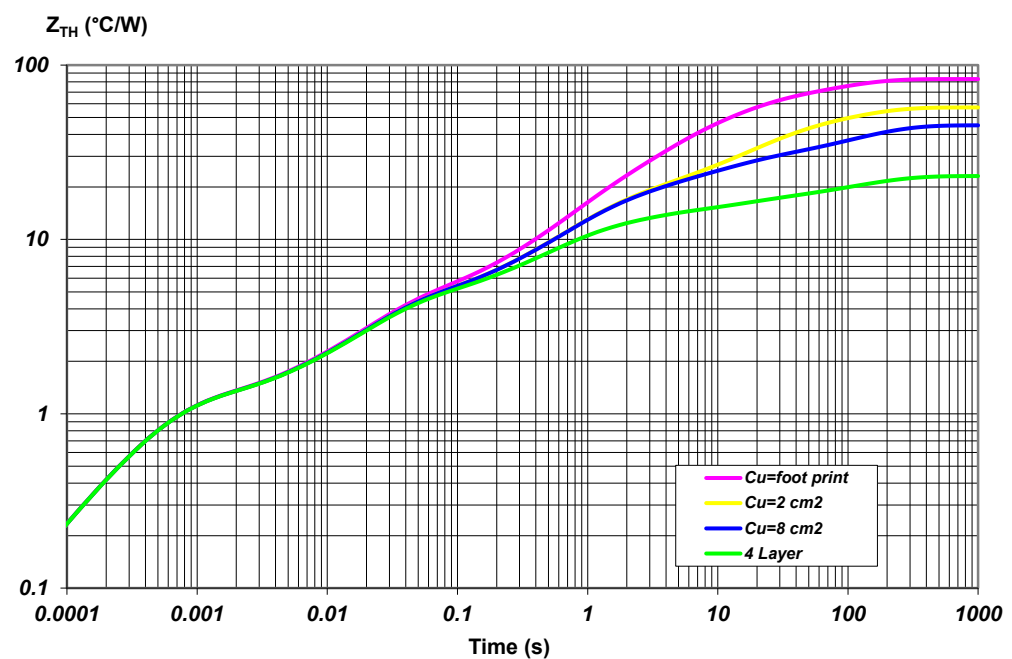
**Table 14. PCB properties**

| Dimension                                     | Value                                             |
|-----------------------------------------------|---------------------------------------------------|
| Board finish thickness                        | 1.6 mm +/- 10%                                    |
| Board dimension                               | 77 mm x 86 mm                                     |
| Board Material                                | FR4                                               |
| Copper thickness (top and bottom layers)      | 0.070 mm                                          |
| Copper thickness (inner layers)               | 0.035 mm                                          |
| Thermal vias separation                       | 1.2 mm                                            |
| Thermal via diameter                          | 0.3 mm +/- 0.08 mm                                |
| Copper thickness on vias                      | 0.025 mm                                          |
| Footprint dimension (top layer)               | 2.2 mm x 3.9 mm                                   |
| Heatsink copper area dimension (bottom layer) | Footprint, 2 cm <sup>2</sup> or 8 cm <sup>2</sup> |

**Figure 46. PowerSSO-16  $R_{thj-amb}$  vs PCB copper area in open box free air condition (one channel on)**


RTHj\_amb on 4Layer PCB: 23.5°C/W

GAPGCFT01141

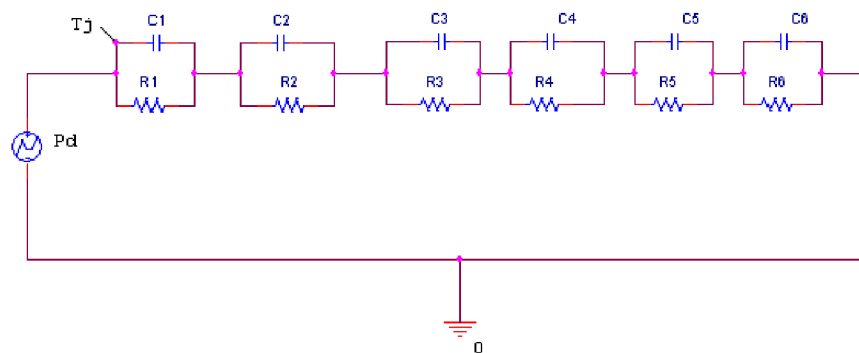
**Figure 47. PowerSSO-16 thermal impedance junction ambient single pulse (one channel on)**


GAPGCFT01142

**Equation: pulse calculation formula**

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp} (1 - \delta)$$

 where  $\delta = t_p/T$

**Figure 48. Thermal fitting model of a double-channel HSD in PowerSSO-16**


TAPG2001151031CFT

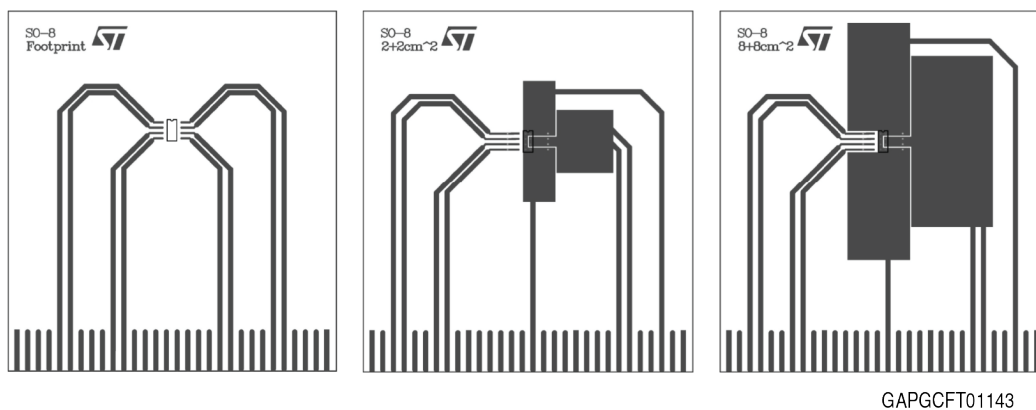
**Note:** The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered.

**Table 15. Thermal parameters**

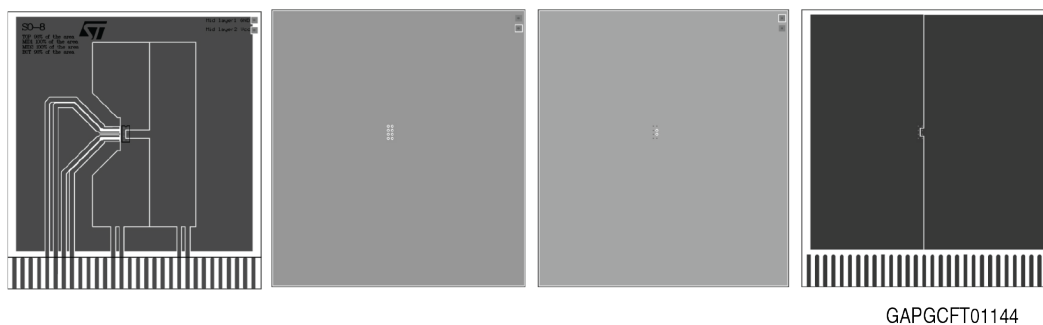
| Area/island (cm <sup>2</sup> ) | Footprint | 2   | 8   | 4L  |
|--------------------------------|-----------|-----|-----|-----|
| R1 (°C/W)                      | 1.1       |     |     |     |
| R2 (°C/W)                      | 3         |     |     |     |
| R3 (°C/W)                      | 7         | 7   | 7   | 5   |
| R4 (°C/W)                      | 16        | 6   | 6   | 4   |
| R5 (°C/W)                      | 30        | 20  | 10  | 3   |
| R6 (°C/W)                      | 26        | 20  | 18  | 7   |
| C1 (W.s/°C)                    | 0.0004    |     |     |     |
| C2 (W.s/°C)                    | 0.008     |     |     |     |
| C3 (W.s/°C)                    | 0.1       |     |     |     |
| C4 (W.s/°C)                    | 0.2       | 0.3 | 0.3 | 0.4 |
| C5 (W.s/°C)                    | 0.4       | 1   | 1   | 4   |
| C6 (W.s/°C)                    | 3         | 5   | 7   | 18  |

## 6.2 SO-8 thermal data

**Figure 49. SO-8 on two-layers PCB (2s0p to JEDEC JESD 51-5)**

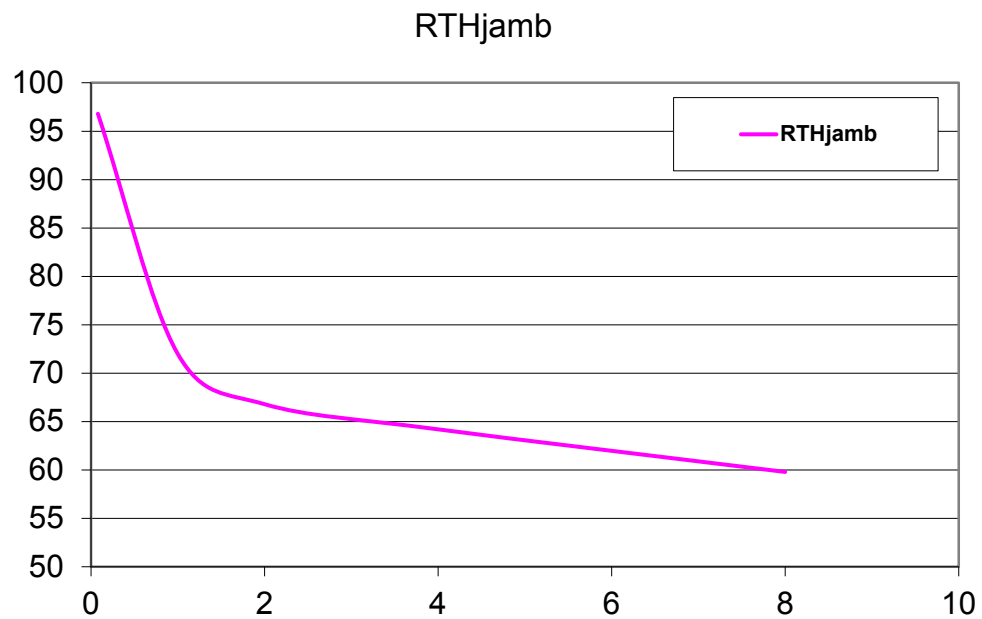


**Figure 50. SO-8 on four-layers PCB (2s2p to JEDEC JESD 51-7)**

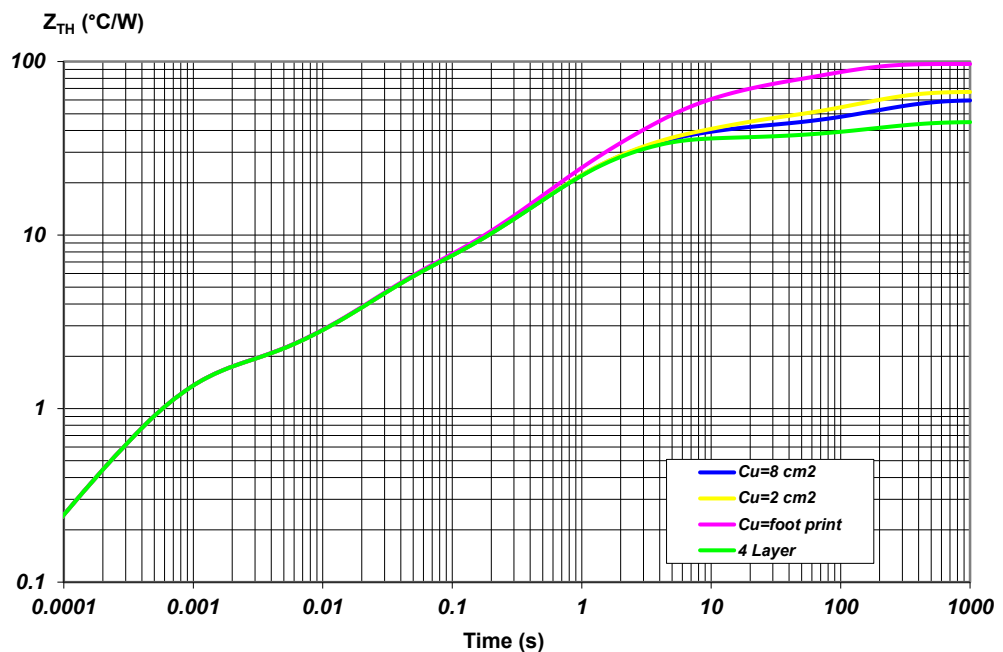


**Table 16. PCB properties**

| Dimension                                     | Value                                                     |
|-----------------------------------------------|-----------------------------------------------------------|
| Board finish thickness                        | 1.6 mm +/- 10%                                            |
| Board dimension                               | 77 mm x 86 mm                                             |
| Board Material                                | FR4                                                       |
| Copper thickness (top and bottom layers)      | 0.070 mm                                                  |
| Copper thickness (inner layers)               | 0.035 mm                                                  |
| Thermal vias separation                       | 1.2 mm                                                    |
| Thermal via diameter                          | 0.3 mm +/- 0.08 mm                                        |
| Copper thickness on vias                      | 0.025 mm                                                  |
| Heatsink copper area dimension (bottom layer) | Footprint, 2 + 2 cm <sup>2</sup> or 8 + 8 cm <sup>2</sup> |

**Figure 51. SO-8  $R_{thj-amb}$  vs PCB copper area in open box free air condition (one channel on)**

 $R_{thj-amb}$  on 4Layer PCB: 45°C/W

GAPGCFT01145

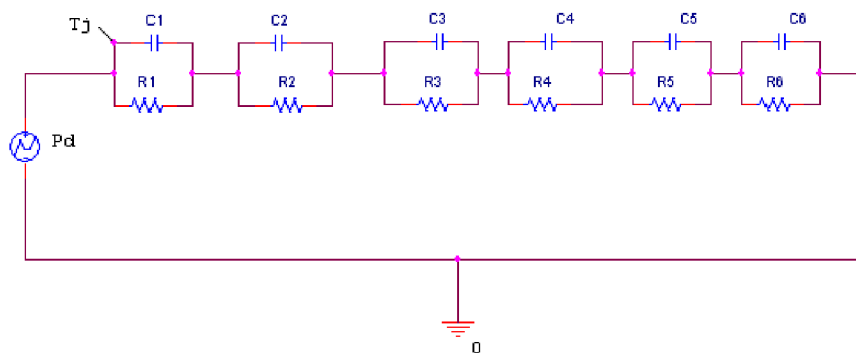
**Figure 52. SO-8 thermal impedance junction ambient single pulse (one channel on)**


GAPGCFT01146

**Equation: pulse calculation formula**

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp} (1 - \delta)$$

where  $\delta = t_p/T$

**Figure 53. Thermal fitting model of a double-channel HSD in SO-8**


TAPG2001151031CFT

**Note:** The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered.

**Table 17. Thermal parameters**

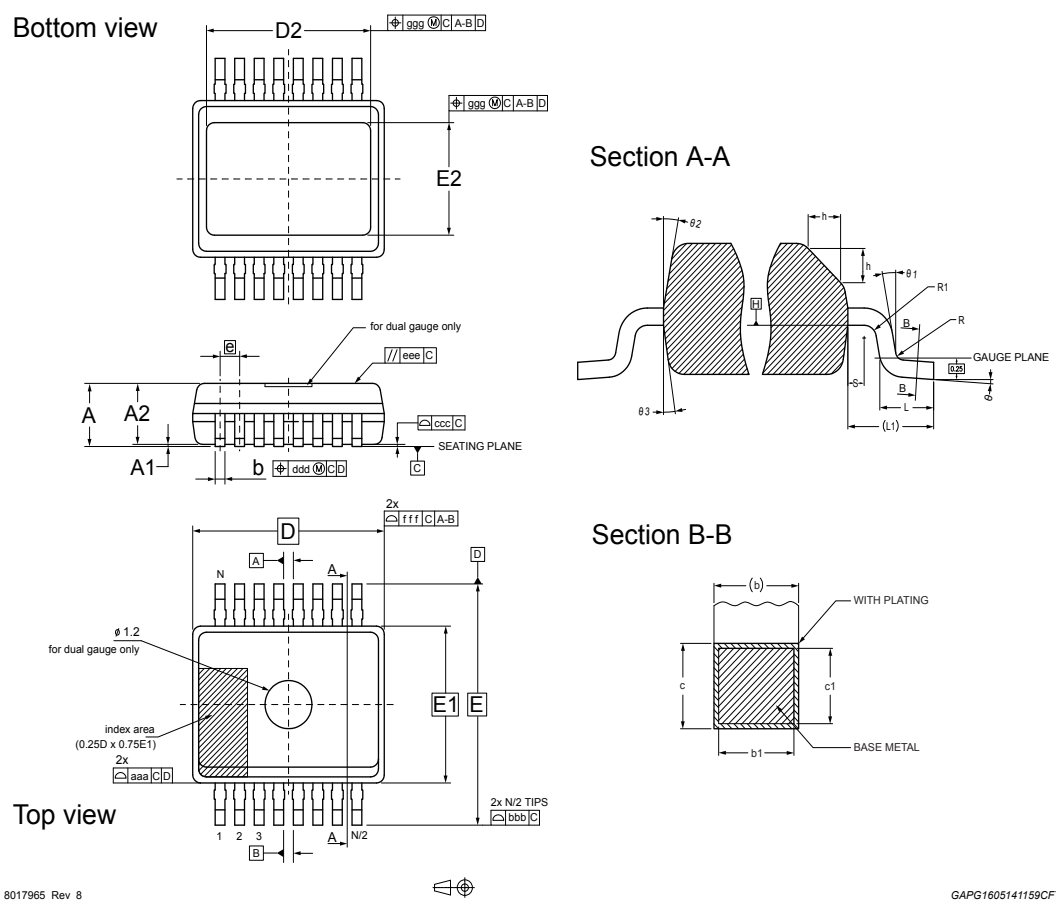
| Area/island (cm <sup>2</sup> ) | Footprint | 2   | 8   | 4L  |
|--------------------------------|-----------|-----|-----|-----|
| R1 (°C/W)                      | 1.5       |     |     |     |
| R2 (°C/W)                      | 3.3       |     |     |     |
| R3 (°C/W)                      | 10        |     |     |     |
| R4 (°C/W)                      | 28        | 17  | 17  | 17  |
| R5 (°C/W)                      | 24        | 12  | 9   | 4   |
| R6 (°C/W)                      | 30        | 23  | 19  | 9   |
| C1 (W.s/°C)                    | 0.0004    |     |     |     |
| C2 (W.s/°C)                    | 0.008     |     |     |     |
| C3 (W.s/°C)                    | 0.05      |     |     |     |
| C4 (W.s/°C)                    | 0.1       |     |     |     |
| C5 (W.s/°C)                    | 0.4       | 0.8 | 0.8 | 0.8 |
| C6 (W.s/°C)                    | 3         | 7   | 11  | 22  |

## 7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 7.1 PowerSSO-16 package information

**Figure 54. PowerSSO-16 package outline**



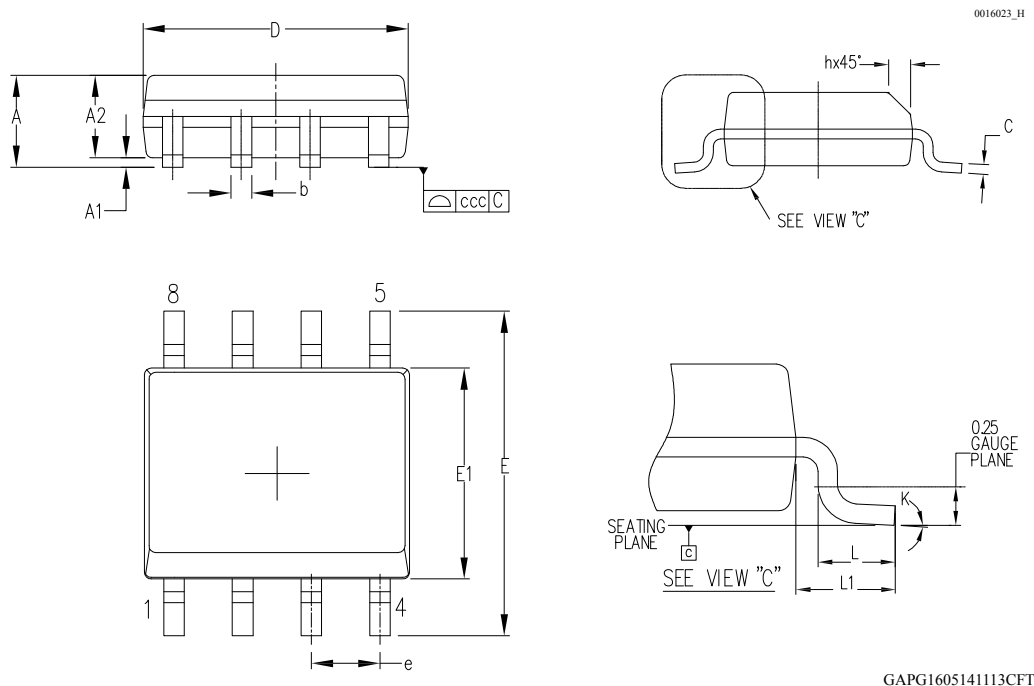
**Table 18. PowerSSO-16 mechanical data**

| Ref. | Dimensions  |      |      |
|------|-------------|------|------|
|      | Millimeters |      |      |
|      | Min.        | Typ. | Max. |
| Θ    | 0°          |      | 8°   |
| Θ1   | 0°          |      |      |
| Θ2   | 5°          |      | 15°  |
| Θ3   | 5°          |      | 15°  |

| Ref.                           | Dimensions  |      |      |
|--------------------------------|-------------|------|------|
|                                | Millimeters |      |      |
|                                | Min.        | Typ. | Max. |
| A                              |             |      | 1.70 |
| A1                             | 0.00        |      | 0.10 |
| A2                             | 1.10        |      | 1.60 |
| b                              | 0.20        |      | 0.30 |
| b1                             | 0.20        | 0.25 | 0.28 |
| c                              | 0.19        |      | 0.25 |
| c1                             | 0.19        | 0.20 | 0.23 |
| D                              | 4.9 BSC     |      |      |
| D1                             | 2.90        |      | 3.50 |
| e                              | 0.50 BSC    |      |      |
| E                              | 6.00 BSC    |      |      |
| E1                             | 3.90 BSC    |      |      |
| E2                             | 2.20        |      | 2.80 |
| h                              | 0.25        |      | 0.50 |
| L                              | 0.40        | 0.60 | 0.85 |
| L1                             | 1.00 REF    |      |      |
| N                              | 16          |      |      |
| R                              | 0.07        |      |      |
| R1                             | 0.07        |      |      |
| S                              | 0.20        |      |      |
| Tolerance of form and position |             |      |      |
| aaa                            | 0.10        |      |      |
| bbb                            | 0.10        |      |      |
| ccc                            | 0.08        |      |      |
| ddd                            | 0.08        |      |      |
| eee                            | 0.10        |      |      |
| fff                            | 0.10        |      |      |
| ggg                            | 0.15        |      |      |

## 7.2 SO-8 package information

**Figure 55. SO-8 package outline**

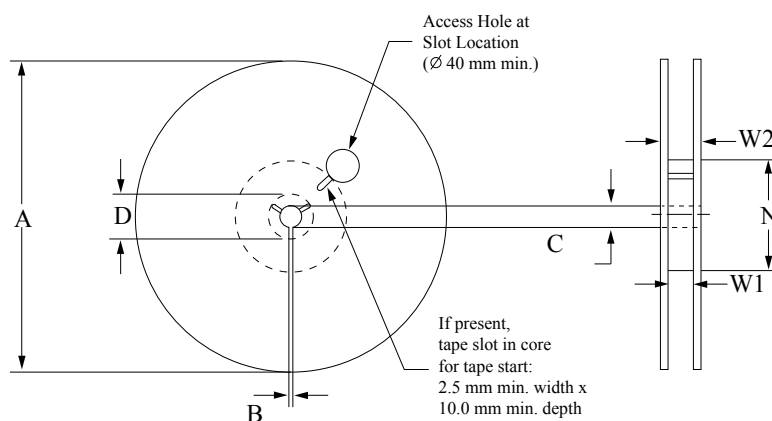


**Table 19. SO-8 mechanical data**

| Ref. | Dimensions  |      |      |
|------|-------------|------|------|
|      | Millimeters |      |      |
|      | Min.        | Typ. | Max. |
| A    |             |      | 1.75 |
| A1   | 0.10        |      | 0.25 |
| A2   | 1.25        |      |      |
| b    | 0.28        |      | 0.48 |
| c    | 0.17        |      | 0.23 |
| D    | 4.80        | 4.90 | 5.00 |
| E    | 5.80        | 6.00 | 6.20 |
| E1   | 3.80        | 3.90 | 4.00 |
| e    |             | 1.27 |      |
| h    | 0.25        |      | 0.50 |
| L    | 0.40        |      | 1.27 |
| L1   |             | 1.04 |      |
| k    | 0°          |      | 8°   |
| ccc  |             |      | 0.10 |

### 7.3 PowerSSO-16 packing information

**Figure 56. PowerSSO-16 reel 13"**



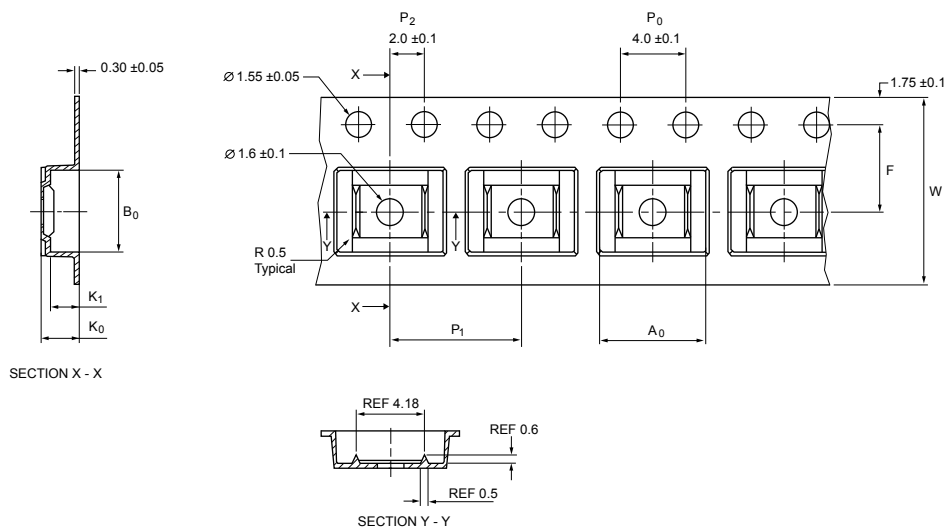
TAPG2004151655CFT

**Table 20. Reel dimensions**

| Description    | Value <sup>(1)</sup> |
|----------------|----------------------|
| Base quantity  | 2500                 |
| Bulk quantity  | 2500                 |
| A (max)        | 330                  |
| B (min)        | 1.5                  |
| C (+0.5, -0.2) | 13                   |
| D (min)        | 20.2                 |
| N              | 100                  |
| W1 (+2 /-0)    | 12.4                 |
| W2 (max)       | 18.4                 |

1. All dimensions are in mm.

**Figure 57. PowerSSO-16 carrier tape**



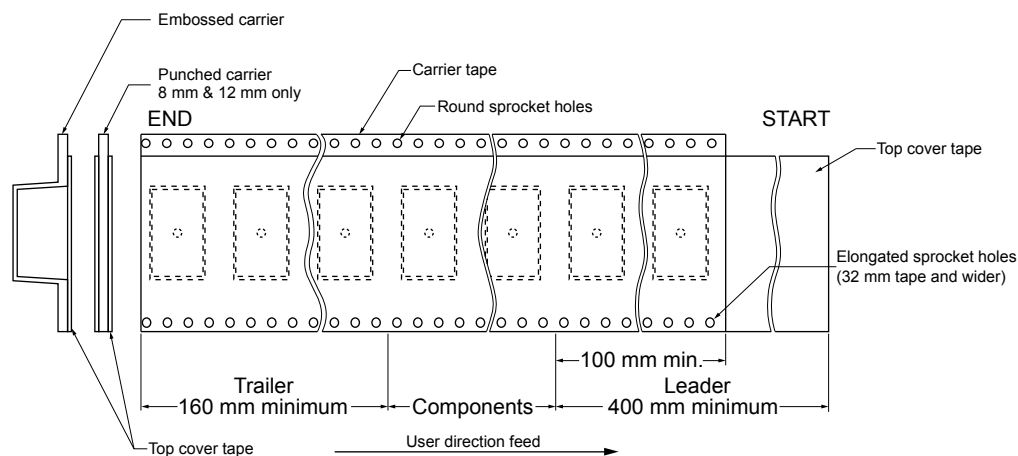
GAPG2204151242CFT

**Table 21. PowerSSO-16 carrier tape dimensions**

| Description    | Value <sup>(1)</sup> |
|----------------|----------------------|
| A <sub>0</sub> | 6.50 ± 0.1           |
| B <sub>0</sub> | 5.25 ± 0.1           |
| K <sub>0</sub> | 2.10 ± 0.1           |
| K <sub>1</sub> | 1.80 ± 0.1           |
| F              | 5.50 ± 0.1           |
| P <sub>1</sub> | 8.00 ± 0.1           |
| W              | 12.00 ± 0.3          |

1. All dimensions are in mm.

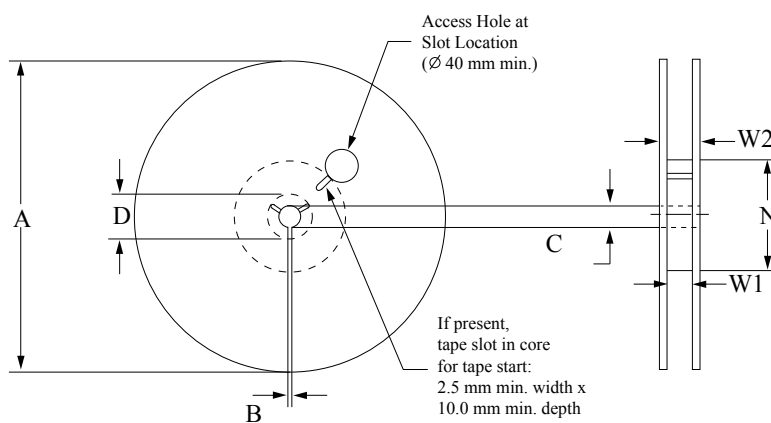
**Figure 58. PowerSSO-16 schematic drawing of leader and trailer tape**



GAPG2004151511CFT

## 7.4 SO-8 packing information

**Figure 59. Reel for SO-8**

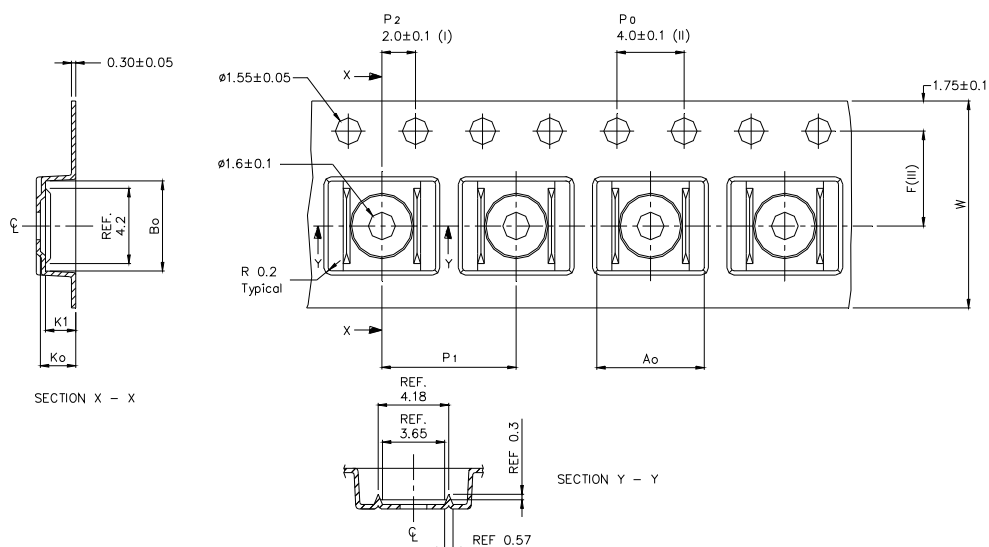


TAPG2004151655CFT

**Table 22. Reel dimensions**

| Description    | Value <sup>(1)</sup> |
|----------------|----------------------|
| Base quantity  | 2500                 |
| Bulk quantity  | 2500                 |
| A (max)        | 330                  |
| B (min)        | 1.5                  |
| C (+0.5, -0.2) | 13                   |
| D (min)        | 20.2                 |
| N              | 100                  |
| W1 (+2/-0)     | 12.4                 |
| W2 (max)       | 18.4                 |

1. All dimensions are in mm.

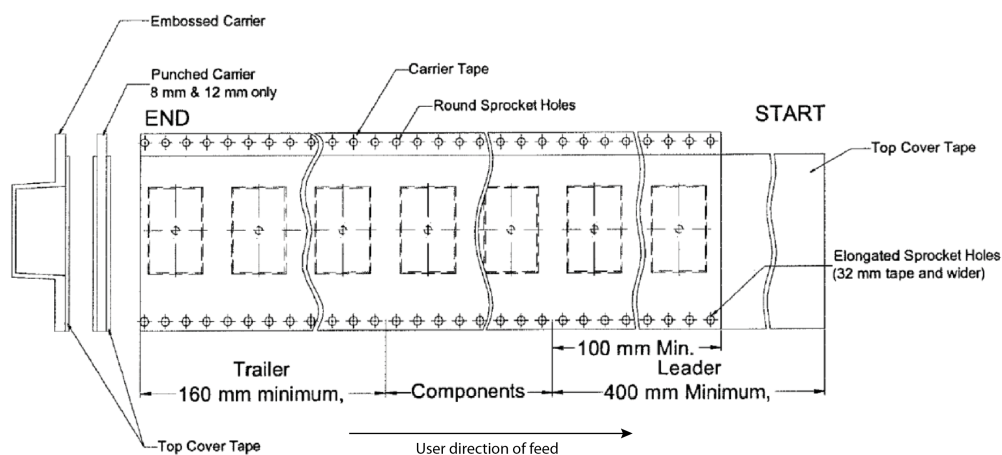
**Figure 60. SO-8 carrier tape**


GAPG2105151447CFT

**Table 23. SO-8 carrier tape dimensions**

| Description | Value <sup>(1)</sup> |
|-------------|----------------------|
| $A_0$       | $6.50 \pm 0.1$       |
| $B_0$       | $5.30 \pm 0.1$       |
| $K_0$       | $2.20 \pm 0.1$       |
| $K_1$       | $1.90 \pm 0.1$       |
| $F$         | $5.50 \pm 0.1$       |
| $P_1$       | $8.00 \pm 0.1$       |
| $W$         | $12.00 \pm 0.3$      |

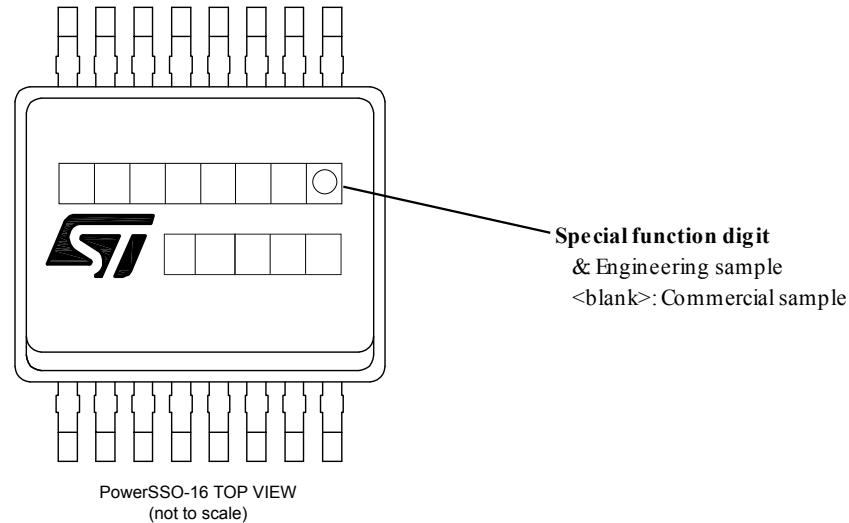
1. All dimensions are in mm.

**Figure 61. SO-8 schematic drawing of leader and trailer tape**


GAPG2004151511CFT

## 7.5 PowerSSO-16 marking information

Figure 62. PowerSSO-16 marking information

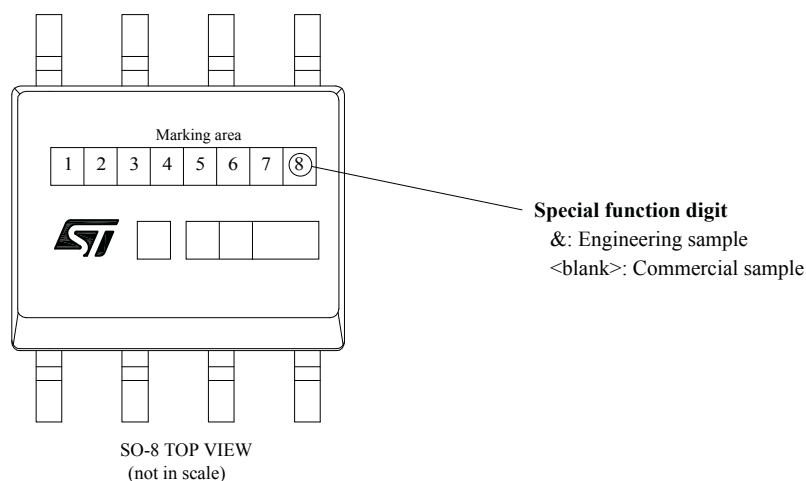


GADG0310161234SMD

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## 7.6 SO-8 marking information

Figure 63. SO-8 marking information



GAPG2705151558CFT

**Note:** *Engineering Samples: these samples can be clearly identified by a dedicated special symbol in the marking of each unit. These samples are intended to be used for electrical compatibility evaluation only; usage for any other purpose may be agreed only upon written authorization by ST. ST is not liable for any customer usage in production and/or in reliability qualification trials.*

*Commercial Samples: fully qualified parts from ST standard production with no usage restrictions*

## 8 Order codes

**Table 24. Device summary**

| Package     | Order codes   |
|-------------|---------------|
|             | Tape and reel |
| PowerSSO-16 | VN7040AJTR    |
| SO-8        | VN7040ASTR    |

## Revision history

**Table 25. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                         |
|-------------|----------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 04-Jun-2015 | 1        | Initial release.                                                                                                                                                                                                                                |
| 20-Jul-2015 | 2        | Updated cover image.<br>Updated <i>Table 4: "Thermal data"</i><br>Updated following sections: <ul style="list-style-type: none"> <li><i>Section 6.1: "PowerSSO-16 thermal data"</i></li> <li><i>Section 6.2: "SO-8 thermal data"</i></li> </ul> |
| 02-Oct-2016 | 3        | Updated the following: <ul style="list-style-type: none"> <li>Features list on the cover page</li> <li><i>Figure 61: "PowerSSO-16 marking information"</i></li> </ul>                                                                           |
| 02-Jul-2018 | 4        | Minor text changes in <a href="#">Section 4.4.2 T<sub>CASE</sub> and V<sub>CC</sub> monitor</a> .                                                                                                                                               |

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